High-Efficiency LED Backlight Driver for Tablets

General Description

LP8556 is a white LED driver featuring an asynchronous boost converter and six high precision current sinks that can be controlled by a PWM signal or an I2C master.

The boost converter uses adaptive output voltage control for setting the optimal LED driver voltages as low as 7V and as high as 43V. This feature minimizes the power consumption by adjusting the output voltage to the lowest sufficient level under all conditions. The converter can operate at three switching frequencies: 312, 625 and 1250 kHz settable with an external resistor or pre-configured via EPROM. Programmable slew rate control and spread spectrum scheme minimize switching noise and improve EMI performance.

LED current sinks can be set with the PWM dimming resolution of up to 15 bits. Proprietary adaptive dimming mode allows higher system power saving. In addition, phase shifted LED PWM dimming allows reduced audible noise and smaller boost output capacitors.

The LP8556 has a full set of safety features that ensure robust operation of the device and external components. The set consists of input under-voltage lockout, thermal shutdown, over-current protection, up to 6 levels of over-voltage protection, LED open and short detection.

The LP8556 operates over the ambient temperature range of -30°C to +85°C. It is available in space saving 20-bump micro SMD and 24-pad LLP packages.

Features

- High efficiency DC/DC boost converter with integrated 0.19Ω power MOSFET and three switching frequency options: 312 / 625 / 1250 kHz
- 2.7V to 36V boost switch input voltage range supports multi-cell Li-Ion batteries (2.7V - 20V VDD input range)
- 7V to 43V boost switch output voltage range supports as few as 3 WLEDs in series per channel and as many as 12
- Configurable channel count (1 to 6)
- Up to 50 mA per channel
- PWM and / or I2C brightness control
- Phase-Shift PWM mode reduces audible noise
- Adaptive dimming for higher LED drive optical efficiency
- Programmable edge-rate control and spread spectrum scheme minimize switching noise and improve EMI performance
- LED fault (short/open) detection, UVLO, TSD, OCP and OVP (up to 6 threshold options)
- Available in tiny 20-bump, 1.715 mm x 2.376 mm x 0.6 mm, 0.4 mm pitch, micro SMD, and 24-pad, 4 mm x 4 mm x 0.8 mm, 0.5 mm pitch, LLP packages.
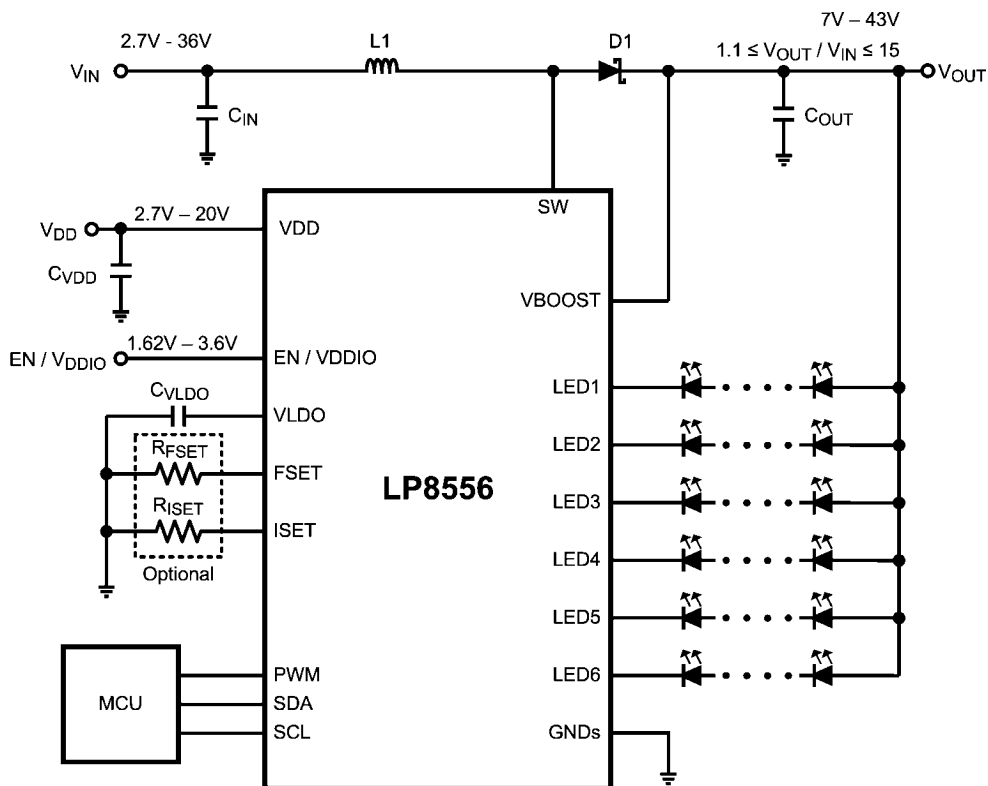
Applications

- Tablet LCD Display LED Backlight

Typical Application

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301626 SNVS871B
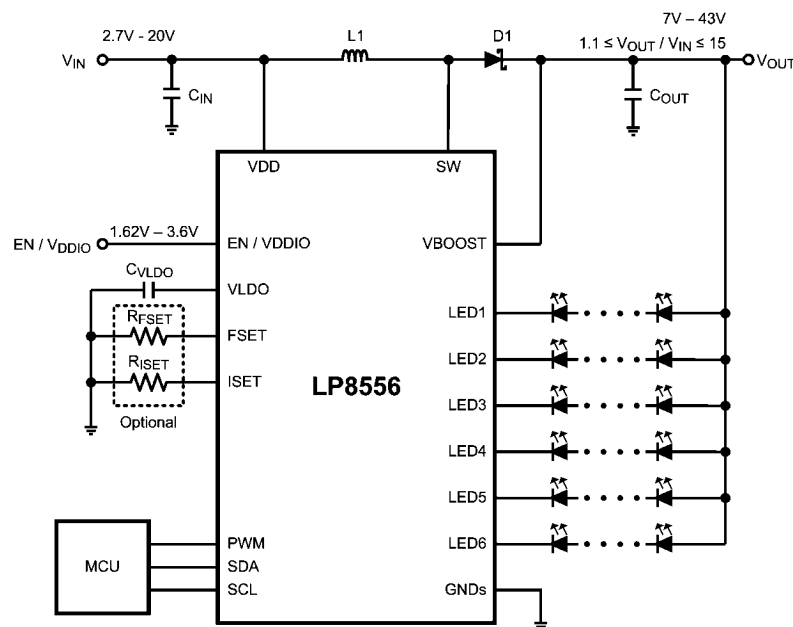
Typical Application (2)

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Recommended Inductance for the Boost Power Stage

Assumes 20 mA as the maximum LED current per string and 3.3V as the maximum LED forward voltage.

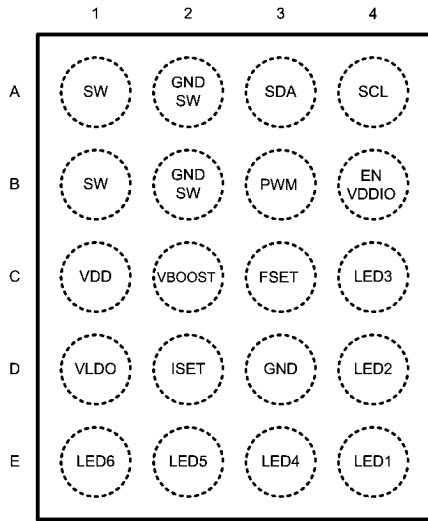| Number of LED Strings	Number of LEDs per String	Boost Input Voltage Range [V]	L1 Inductance [µH]		
			f_{SW} = 1250 kHz	f_{SW} = 625 kHz	f_{SW} = 312 kHz
6	6	2.7V - 4.4V	3.3 µH - 6.8 µH	6.8 µH - 15 µH	10 µH - 33 µH
		5.4V - 8.8V	10 µH - 22 µH	22 µH - 47 µH	47 µH - 100 µH
6	8	2.7V - 4.4V	4.7 µH - 10 µH	10 µH - 15 µH	22 µH - 33 µH
		5.4V - 8.8V	10 µH - 22 µH	22 µH - 68 µH	47 µH - 100 µH
4	10	5.4V - 8.8V	6.8 µH - 22 µH	22 µH - 47 µH	47 µH - 100 µH
4	12	5.4V - 8.8V	10 µH - 22 µH	22 µH - 47 µH	33 µH - 100 µH

Recommended Capacitances for the Boost and LDO Power Stages (*Note 1*)

Switching Frequency [kHz]	C_{IN} [µF]	C_{OUT} [µF]	C_{VLDO} [µF]
1250	2.2	4.7	10
625	2.2	4.7	10
312	4.7	10	10

Note 1: Capacitance of Multi Layer Ceramic Capacitors (MLCC) can change significantly with the applied DC voltage. Use capacitors with good capacitance vs. DC bias characteristics. In general, MLCC in bigger packages have lower capacitance de-rating than physically smaller capacitors.
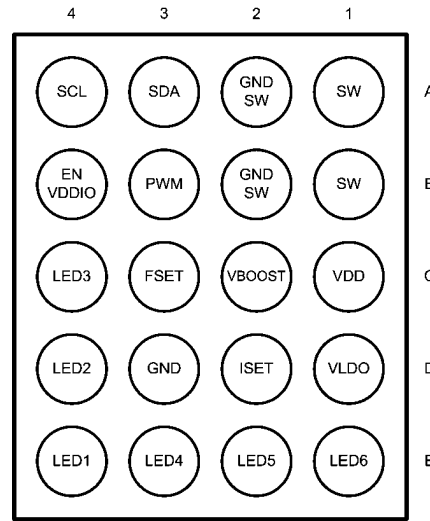
Connection Diagrams and Package Mark Information (Micro SMD)

20-bump Micro SMD Package
1.715 mm x 2.376 mm x 0.6 mm, 0.4 mm pitch
NS Package Number TMD20EQA

	1	2	3	4
A	SW	GND SW	SDA	SCL
B	SW	GND SW	PWM	EN VDDIO
C	VDD	VBOOST	FSET	LED3
D	VLDO	ISET	GND	LED2
E	LED6	LED5	LED4	LED1

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Top View

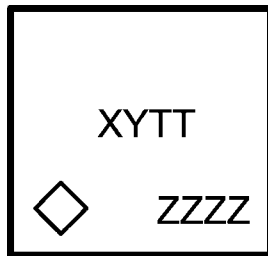|	4	3	2	1	
A	SCL	SDA	GND SW	SW	
B	EN VDDIO	PWM	GND SW	SW	
C	LED3	FSET	VBOOST	VDD	
D	LED2	GND	ISET	VLDO	
E	LED1	LED4	LED5	LED6	

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Bottom View

Package Mark (Micro SMD)

XYTT

◇ ZZZZ

XY = 2 Digit Date Code

TT = Die Traceability

ZZZZ = Product Identification

◇ = Pin 1A

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Package Mark - Top View

Ordering Information (Micro SMD)

Order Number	Spec / Flow	Package Marking	Supplied As
LP8556TMX-E00	S7003001	56E0	3000 units, Tape-and-Reel
LP8556TME-E01	NoPb	56E1	250 units, Tape-and-Reel
LP8556TMX-E01	NoPb	56E1	3000 units, Tape-and-Reel
LP8556TME-E02	NoPb	56E2	250 units, Tape-and-Reel
LP8556TMX-E02	NoPb	56E2	3000 units, Tape-and-Reel
LP8556TME-E03	NoPb	56E3	250 units, Tape-and-Reel
LP8556TMX-E03	NoPb	56E3	3000 units, Tape-and-Reel
LP8556TME-E04	NoPb	56E4	250 units, Tape-and-Reel
LP8556TMX-E04	NoPb	56E4	3000 units, Tape-and-Reel
LP8556TME-E05	NoPb	56E5	250 units, Tape-and-Reel
LP8556TMX-E05	NoPb	56E5	3000 units, Tape-and-Reel
LP8556TME-E06	NoPb	56E6	250 units, Tape-and-Reel
LP8556TMX-E06	NoPb	56E6	3000 units, Tape-and-Reel
LP8556TME-E07	NoPb	56E7	250 units, Tape-and-Reel
LP8556TMX-E07	NoPb	56E7	3000 units, Tape-and-Reel
LP8556TMX-E08	S7003057	56E8	3000 units, Tape-and-Reel
LP8556TMX-E09	S7003056	56E9	3000 units, Tape-and-Reel
LP8556TME-E10	NoPb	6E10	250 units, Tape-and-Reel
LP8556TMX-E10	NoPb	6E10	3000 units, Tape-and-Reel

Ordering Information (LLP)

Order Number	Spec/Flow	Package Marking	Supplied As
LP8556SQE-E00	NoPb	L8556E0	250 units, Tape-and-Reel
LP8556SQX-E00	NoPb	L8556E0	4500 units, Tape-and-Reel
LP8556SQE-E08	NoPb	L8556E8	250 units, Tape-and-Reel
LP8556SQX-E08	NoPb	L8556E8	4500 units, Tape-and-Reel
LP8556SQE-E09	NoPb	L8556E9	250 units, Tape-and-Reel
LP8556SQX-E09	NoPb	L8556E9	4500 units, Tape-and-Reel

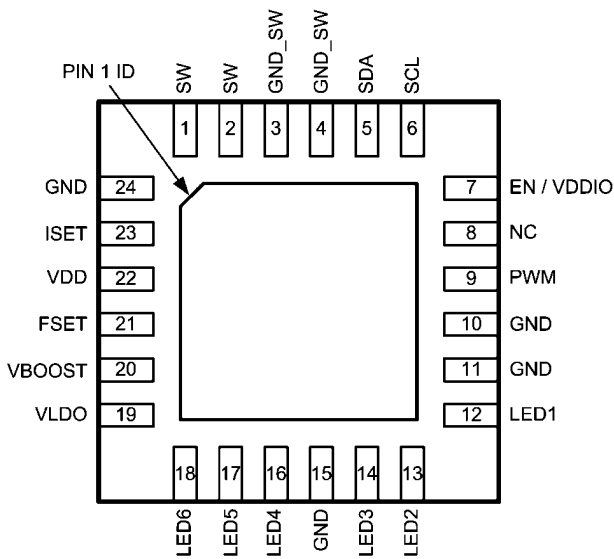# Connection Diagrams and Package Mark Information (LLP)

24–pin Leadless Leadframe Package (LLP)
4.0 x 4.0 x 0.8mm, 0.5 mm pitch
NS Package Number SQA24A
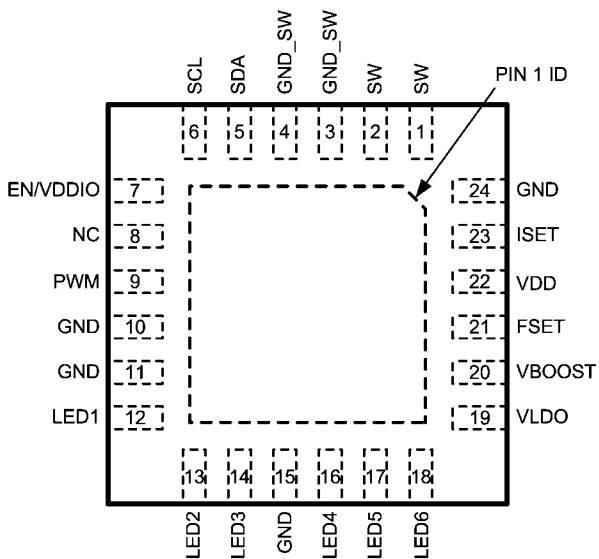
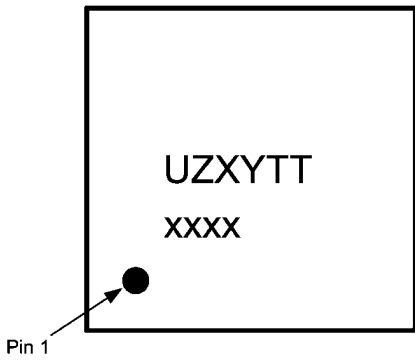**Top View**

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Bottom View

30162672

Package Mark (LLP)

UZXYTT

XXXX

Pin 1

30162696

Package Mark - Top View

U = Fab
Z = Assembly
XY = 2–Digit Date Code
TT = Die Traceability
xxxx = Product Identification

Pin Descriptions

uSMD	LLP	Name	Type	Description
A1, B1	1, 2	SW	A	A connection to the drain terminal of the integrated power MOSFET.
A2, B2	3, 4	GND_SW	G	A connection to the source terminal of the integrated power MOSFET.
A3	5	SDA	I/O	I²C data input/output pin.
A4	6	SCL	I	I²C clock input pin.
B3	9	PWM	I	PWM dimming input. Supply a 75 Hz to 25 kHz PWM signal to control dimming. This pin must be connected to GND if unused.
B4	7	EN / VDDIO	P	Dual purpose pin serving both as a Chip enable and as a power supply reference for PWM, SDA and SCL inputs. Drive this pin with a logic gate capable of sourcing a minimum of 1 mA.
C1	22	VDD	P	Device power supply pin. Provide 2.7V to 20V supply to this pin. This pin is an input of the internal LDO regulator. The output of the internal LDO is what powers the device.
C2	20	VBOOST	A	Boost converter output pin. The internal Feedback (FB) and Over-voltage Protection (OVP) circuitry monitors the voltage on this pin. Connect the converter output capacitor bank close to this pin.
C3	21	FSET	A	A connection for setting the boost frequency and PWM output dimming frequency by using an external resistor. Connect a resistor, R_{FSET}, between this pin and the ground reference (See *Table 5*). This pin may be left floating if PWM_FSET_EN=0 AND BOOST_FSET_EN=0 (See *EPROM Memory Map*).
C4	14	LED3	A	LED driver - current sink terminal. If unused, it may be left floating.
D1	19	VLDO	P	Internal LDO output pin. Connect a capacitor, C_{VLDO}, between this pin and the ground reference.
D2	23	ISET	A	A connection for the LED current set resistor. Connect a resistor, R_{ISET}, between this pin and the ground reference. This pin may be left floating if ISET_EN=0 (See *EPROM Memory Map*).
D3	10, 11, 15, 24, DAP	GND	I	Ground pin.
D4	13	LED2	A	LED driver - current sink terminal. If unused, it may be left floating.
E1	18	LED6	A	LED driver - current sink terminal. If unused, it may be left floating.
E2	17	LED5	A	LED driver - current sink terminal. If unused, it may be left floating.
E3	16	LED4	A	LED driver - current sink terminal. If unused, it may be left floating.
E4	12	LED1	A	LED driver - current sink terminal. If unused, it may be left floating.
-	8	NC	-	No Connect pin.

A: Analog Pin, G: Ground Pin, P: Power Pin, I: Digital Input Pin, I/O: Digital Input/Output Pin

Absolute Maximum Ratings (*Note 4*)

If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.

	Min	Max	Units
V_{DD}	-0.3	24	V
Voltage on Logic Pins (SCL, SDA, PWM)	-0.3	6	V
Voltage on Analog Pins (VLDO, EN / VDDIO)	-0.3	6	V
Voltage on Analog Pins (FSET, ISET)	-0.3	VLDO+0.3	V
V (LED1...LED6,SW, VBOOST)	-0.3	50	V
Junction Temperature (T_{J-MAX}) (*Note 6*)		125	°C
Storage Temperature Range	-65	150	°C
Maximum Lead Temperature (Soldering)		260	°C
HBM (*Note 2*)	2		kV
CDM (*Note 3*)	500		V

Note 2: Human Body Model, applicable std. JESD22-A114C

Note 3: Field Induced Charge Device Model, applicable std. JESD22-C101-C

Operating Ratings (*Note 4*, *Note 5*)

	Min	Max	Units
VDD Range	2.7	20	V
EN / VDDIO Range	1.62	3.6	V
V (LED1...LED6, SW, VBOOST)	0	48	V
Junction Temperature Range (T_J)	-30	125	°C
Ambient Temperature Range (T_A)	-30	85	°C

Thermal Properties (*Note 7*)

	Min	Max	Units
Junction-to-Ambient Thermal Resistance (θ_{JA}), TMD Package	40	73	°C/W
Junction-to-Ambient Thermal Resistance (θ_{JA}), SQA Package	35	50	°C/W

Electrical Characteristics (*Note 5*, *Note 8*)

Limits in standard typeface are for T_A = 25 °C. Limits in **boldface** type apply over the full operating ambient temperature range (-30 °C ≤ T_A ≤ +85 °C). Unless otherwise specified: VDD=12V, EN / VDDIO = 1.8V

Symbol	Parameter	Condition	Min	Typ	Max	Units
V_{DDIO}	Supply voltage for digital I/Os		1.62		3.6	V
V_{DD}	Input voltage for the internal LDO		2.7		20	V
I_{DD}	Standby Supply Current	EN / VDDIO=0V, LDO disabled			**1.6**	μA
	Normal Mode Supply Current	LDO enabled, Boost disabled		0.9	1.5	mA
		LDO enabled, Boost enabled, no load		2.2	3.65	
f_{OSC}	Internal Oscillator Frequency Accuracy		-4 **-7**		+4 **+7**	%
V_{LDO}	LDO Output Voltage	V_{DD} ≥ 3.1V	2.95	3.05	3.15	V
		2.7V ≤ V_{DD} < 3.1V		V_{DD} - 0.05		
T_{TSD}	Thermal Shutdown Threshold	(*Note 9*)		150		°C
T_{TSD_hyst}	Thermal Shutdown Hysteresis			20		°C

Note 4: Absolute Maximum Ratings indicate limits beyond which damage to the component may occur. Operating Ratings are conditions under which operation of the device is guaranteed. Operating Ratings do not imply guaranteed performance limits. For guaranteed performance limits and associated test conditions, see the Electrical Characteristics tables.

Note 5: All voltages are with respect to the potential at the GND pins.

Note 6: In applications where high power dissipation and/or poor package thermal resistance is present, the maximum ambient temperature may have to be derated. Maximum ambient temperature (T_{A-MAX}) is dependent on the maximum operating junction temperature ($T_{J-MAX-OP}$ = 125 °C), the maximum power dissipation of the device in the application (P_{D-MAX}), and the junction-to ambient thermal resistance of the part/package in the application ($θ_{JA}$), as given by the following equation: $T_{A-MAX} = T_{J-MAX-OP} - (θ_{JA} × P_{D-MAX})$.

Note 7: Junction-to-ambient thermal resistance is highly application and board-layout dependent. In applications where high maximum power dissipation exists, special care must be paid to thermal dissipation issues in board design.

Note 8: Min and Max limits are guaranteed by design, test, or statistical analysis. Typical numbers are not guaranteed, but do represent the most likely norm.

Note 9: Guaranteed by design and not tested in production.

Boost Converter Electrical Characteristics (*Note 12*)

Symbol	Parameter	Condition	Min	Typ	Max	Units
R_{DS_ON}	Switch ON resistance	I_{SW} = 0.5A		0.19		Ω
V_{BOOST_MIN}	Boost minimum output voltage	VBOOST_RANGE = 0 VBOOST_RANGE = 1		7 16		V
V_{BOOST_MAX}	Boost maximum output voltage	VBOOST_MAX = 100, VBOOST_RANGE = 0 VBOOST_MAX = 101, VBOOST_RANGE = 0 VBOOST_MAX = 110, VBOOST_RANGE = 0 VBOOST_MAX = 111, VBOOST_RANGE = 0	19.0 24.0 28.0 32	21 25 30 34	22 27 32 37	V
		VBOOST_MAX = 010, VBOOST_RANGE = 1 VBOOST_MAX = 011, VBOOST_RANGE = 1 VBOOST_MAX = 100, VBOOST_RANGE = 1 VBOOST_MAX = 101, VBOOST_RANGE = 1 VBOOST_MAX = 110, VBOOST_RANGE = 1 VBOOST_MAX = 111, VBOOST_RANGE = 1	17.9 22.8 27.8 32.7 37.2 41.8	21 25 30 34.5 39 43	23.1 27.2 31.5 36.6 40.8 44.2	V
I_{LOAD_MAX}	Maximum continuous output load current	V_{IN} = 3V, V_{OUT} = 18V V_{IN} = 3V, V_{OUT} = 24V V_{IN} = 3V, V_{OUT} = 30V		220 160 120		mA
V_{OUT}/V_{IN}	Conversion ratio (*Note 13*)	f_{SW} = 625 kHz f_{SW} = 1250 kHz			15 12	
f_{SW}	Switching frequency	BOOST_FREQ = 00 BOOST_FREQ = 01 BOOST_FREQ = 10		312 625 1250		kHz
V_{OVP}	Over-voltage protection voltage	VBOOST_RANGE = 1		V_{BOOST} + 1.6V		V
V_{UVLO}	V_{IN} under-voltage lockout threshold	UVLO_EN=1 UVLO_TH = 0, falling UVLO_TH = 1, falling		2.5 5.2		V
V_{UVLO_hyst}	V_{UVLO} hysteresis	V_{UVLO}[rising] - V_{UVLO}[falling] UVLO_TH = 0 UVLO_TH = 1		50 100		mV
t_{PULSE}	Switch minimum pulse width	no load		50		ns
$t_{STARTUP}$	Startup time	(*Note 10*)		8		ms

Boost Converter Electrical Characteristics (Continued)

Symbol	Parameter	Condition		Min	Typ	Max	Units
I_{SW_LIM}	SW pin current limit (*Note 11*)	IBOOST_LIM_2X = 0	IBOOST_LIM = 00	0.66	0.9	1.16	A
			IBOOST_LIM = 01	0.88	1.2	1.40	
			IBOOST_LIM = 10	1.12	1.5	1.73	
			IBOOST_LIM = 11	1.35	1.8	2.07	
		IBOOST_LIM_2X = 1	IBOOST_LIM = 00		1.6		A
			IBOOST_LIM = 01		2.1		
			IBOOST_LIM = 10		2.6		
$\Delta V_{SW} / t_{off\_on}$	SW pin slew rate during OFF to ON transition	EN_DRV3 = 0 AND EN_DRV2 = 0			3.7		V / ns
		EN_DRV3 = 0 AND EN_DRV2 = 1			5.3		
		EN_DRV3 = 1 AND EN_DRV2 = 1			7.5		
$\Delta V_{SW} / t_{on\_off}$	SW pin slew rate during ON to OFF transition	EN_DRV3 = 0 AND EN_DRV2 = 0			1.9		V / ns
		EN_DRV3 = 0 AND EN_DRV2 = 1			4.4		
		EN_DRV3 = 1 AND EN_DRV2 = 1			4.8		
$\Delta t_{ON} / t_{SW}$	Peak to peak switch ON time deviation to SW period ratio (Spread spectrum feature)	SSCLK_EN = 1			1		%

Note 10: Startup time is measured from the moment boost is activated until the VBOOST crosses 90% of its target value.

Note 11: 1.8A is the maximum I_{SW_LIM} supported with the Micro SMD package. For applications requiring the I_{SW_LIM} to be greater than 1.8A and up to 2.6A, LLP package should be considered.

Note 12: Min and Max limits are guaranteed by design, test, or statistical analysis. Typical numbers are not guaranteed, but do represent the most likely norm.

Note 13: Guaranteed by design and not tested in production.

LED Driver Electrical Characteristics (*Note 16*)

Symbol	Parameter	Condition	Min	Typ	Max	Units
$I_{LED\_LEAKAGE}$	Leakage current	Outputs LED1...LED6, V_{OUT} = 48V		0.1	**1**	µA
I_{LED_MAX}	Maximum Sink Current LED1...LED6			50		mA
I_{LED}	LED Current Accuracy (*Note 14*)	Output current set to 23 mA	-3 **-4**	1	+3 **+4**	%
I_{MATCH}	Matching	Output current set to 23 mA		0.5		%
PWM_{DUTY}	LED PWM output pulse duty cycle (*Note 17*)	100 Hz < f_{PWM} ≤ 200 Hz	0.02		100	%
		200 Hz < f_{PWM} ≤ 500 Hz	0.02		100	
		500 Hz < f_{PWM} ≤ 1 kHz	0.02		100	
		1 kHz < f_{PWM} ≤ 2 kHz	0.04		100	
		2 kHz < f_{PWM} ≤ 5 kHz	0.1		100	
		5 kHz < f_{PWM} ≤ 10 kHz	0.2		100	
		10 kHz < f_{PWM} ≤ 20 kHz	0.4		100	
		20 kHz < f_{PWM} ≤ 30 kHz	0.6		100	
		30 kHz < f_{PWM} ≤ 39 kHz	0.8		100	
f_{LED}	PWM output frequency	PWM_FREQ = 1111		38.5		kHz
V_{SAT}	Saturation Voltage (*Note 15*)	Output current set to 23 mA		200		mV

Note 14: Output Current Accuracy is the difference between the actual value of the output current and programmed value of this current. Matching is the maximum difference from the average. For the constant current sinks on the part (OUT1 to OUT6), the following are determined: the maximum output current (MAX), the minimum output current (MIN), and the average output current of all outputs (AVG). Two matching numbers are calculated: (MAX-AVG)/AVG and (AVG-MIN/AVG). The largest number of the two (worst case) is considered the matching figure. The typical specification provided is the most likely norm of the matching figure for all parts. Note that some manufacturers have different definitions in use.

Note 15: Saturation voltage is defined as the voltage when the LED current has dropped 10% from the value measured at 1V.

Note 16: Min and Max limits are guaranteed by design, test, or statistical analysis. Typical numbers are not guaranteed, but do represent the most likely norm.

Note 17: Guaranteed by design and not tested in production.

PWM Interface Characteristics (*Note 18*)

Symbol	Parameter	Condition	Min	Typ	Max	Units
f_{PWM}	PWM Frequency Range (*Note 19*)		75		25000	Hz
t_{MIN_ON}	Minimum Pulse ON time			1		μs
t_{MIN_OFF}	Minimum Pulse OFF time			1		
$t_{STARTUP}$	Turn on delay from standby to backlight on	PWM input active, VDDIO pin transitions from 0V to 1.8V.		10		ms
t_{STBY}	Turn off delay	PWM input low time for turn off		50		ms
PWM_{RES}	PWM Input Resolution	$f_{IN} < 9.0$ kHz		8		bits

Logic Interface Characteristics (*Note 18*)

Symbol	Parameter	Condition	Min	Typ	Max	Units
Logic Inputs (PWM, SDA, SCL)						
V_{IL}	Input Low Level				**0.3 X VDDIO**	V
V_{IH}	Input High Level		**0.7 X VDDIO**			V
I_I	Input Current	(V_{DDIO} = 0V or 3.6V) AND (V_I = 0V or 3.6V)	**-1.0**		**1.0**	μA
Logic Outputs (SDA)						
V_{OL}	Output Low Level	I_{OUT} = 3 mA (pull-up current)		0.3	**0.4**	V
I_L	Output Leakage Current	V_{OUT} = 5V	**-1.0**		**1.0**	μA

Note 18: Min and Max limits are guaranteed by design, test, or statistical analysis. Typical numbers are not guaranteed, but do represent the most likely norm.
**Note 19:** Guaranteed by design and not tested in production.

I2C Serial Bus Timing Parameters (SDA, SCL) (*Note 21*)

Symbol	Parameter	Limit		Units
		Min	Max	
f_{SCL}	Clock Frequency		400	kHz
1	Hold Time (repeated) START Condition	0.6		µs
2	Clock Low Time	1.3		µs
3	Clock High Time	600		ns
4	Setup Time for a Repeated START Condition	600		ns
5	Data Hold Time	50		ns
6	Data Setup Time	100		ns
7	Rise Time of SDA and SCL	$20+0.1C_b$	300	ns
8	Fall Time of SDA and SCL	$15+0.1C_b$	300	ns
9	Set-up Time for STOP condition	600		ns
10	Bus Free Time between a STOP and a START Condition	1.3		µs
C_b	Capacitive Load Parameter for Each Bus Line Load of 1 pF corresponds to 1 ns.	10	200	ns

Note 20: Min and Max limits are guaranteed by design, test, or statistical analysis. Typical numbers are not guaranteed, but do represent the most likely norm.

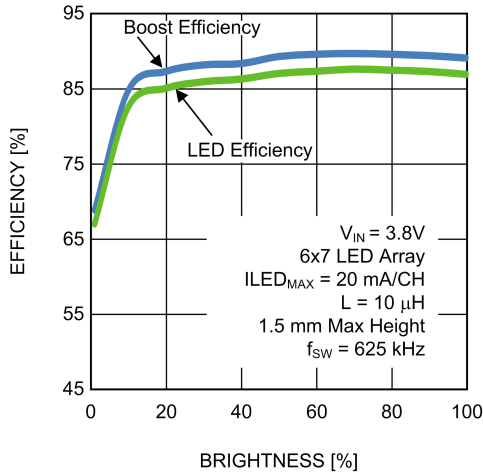**Note 21:** Guaranteed by design and not tested in production.
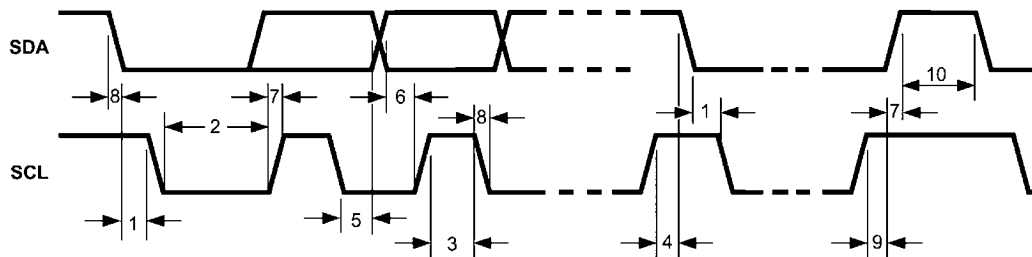
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FIGURE 1. I2C Compatible Timing
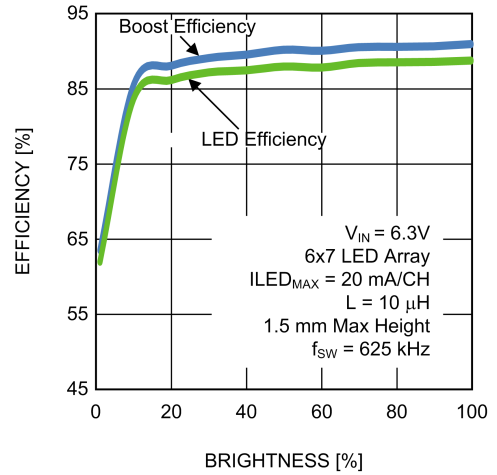
Typical Performance Characteristics

Unless otherwise specified: V_{IN} = 3.8V, C_{VLDO} = 10 µF, L1 = 4.7 µH, C_{IN} = 2.2 µF, C_{OUT} = 4.7 µF, f_{SW} = 1.25 MHz
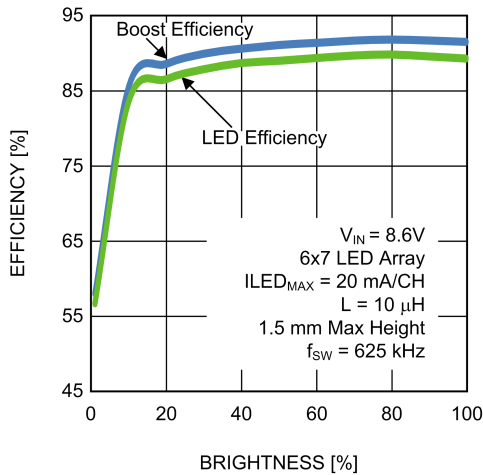
Boost and LED Drive Efficiency, V_{IN} = 3.8V

Boost Efficiency

LED Efficiency

V_{IN} = 3.8V
6x7 LED Array
$ILED_{MAX}$ = 20 mA/CH
L = 10 µH
1.5 mm Max Height
f_{SW} = 625 kHz

EFFICIENCY [%]

BRIGHTNESS [%]

30162652

Boost and LED Drive Efficiency, V_{IN} = 6.3V

Boost Efficiency

LED Efficiency

V_{IN} = 6.3V
6x7 LED Array
$ILED_{MAX}$ = 20 mA/CH
L = 10 µH
1.5 mm Max Height
f_{SW} = 625 kHz

EFFICIENCY [%]

BRIGHTNESS [%]

30162653

Boost and LED Drive Efficiency, V_{IN} = 8.6V

Boost Efficiency

LED Efficiency

V_{IN} = 8.6V
6x7 LED Array
$ILED_{MAX}$ = 20 mA/CH
L = 10 µH
1.5 mm Max Height
f_{SW} = 625 kHz

EFFICIENCY [%]

BRIGHTNESS [%]

30162654

Boost and LED Drive Efficiency, V_{IN} = 12.9V

Boost Efficiency

LED Efficiency

V_{IN} = 12.9V
6x7 LED Array
$ILED_{MAX}$ = 20 mA/CH
L = 10 µH
1.5 mm Max Height
f_{SW} = 625 kHz

EFFICIENCY [%]
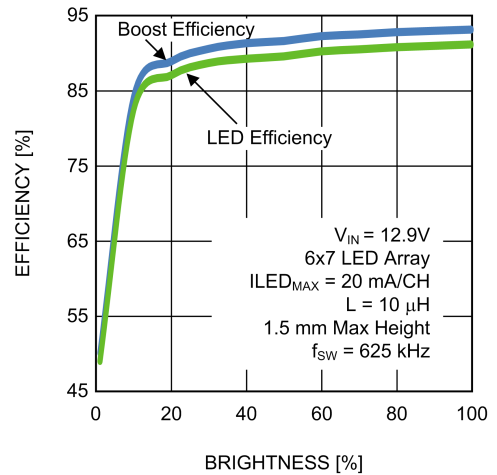
BRIGHTNESS [%]

30162655

Optical Efficiency with 10" Panel

Adaptive Dimming

PWM Dimming

V_{IN} = 3.6V
10" Panel
6x7 LED Array
$ILED_{MAX}$ = 23 mA/CH
L = 4.7 µH
1.5 mm Max Height
f_{SW} = 1.25 MHz

OPTICAL EFFICIENCY [Nits/W]
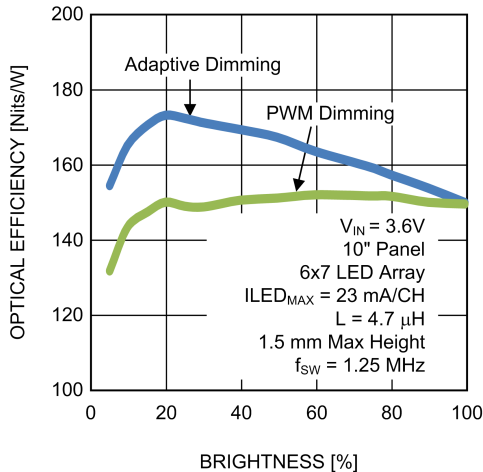
BRIGHTNESS [%]

30162656

Luminance as a Function of Brightness

Adaptive Dimming

PWM Dimming

V_{IN} = 3.6V
10" Panel
6x7 LED Array
$ILED_{MAX}$ = 23 mA/CH
L = 4.7 µH
1.5 mm Max Height
f_{SW} = 1.25 MHz

LUMINANCE [Nits]
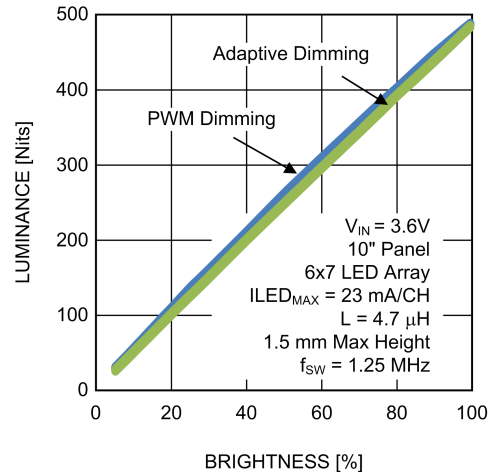
BRIGHTNESS [%]

30162657

Input Power as a Function of Brightness

V$_{IN}$ = 3.6V
10" Panel
6x7 LED Array
ILED$_{MAX}$ = 23 mA/CH
L = 4.7 µH
1.5 mm Max Height
f$_{SW}$ = 1.25 MHz

PWM Dimming

Adaptive Dimming

INPUT POWER [W] vs LUMINANCE [Nits]
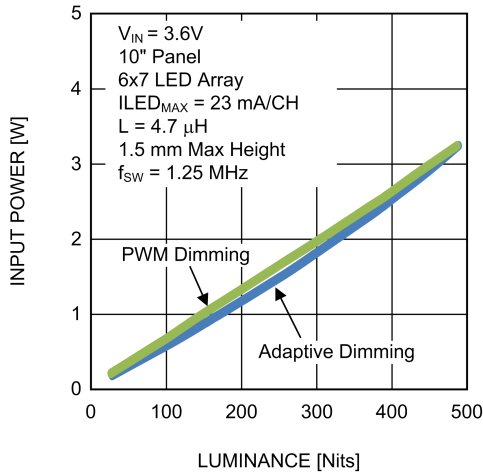
30162658

Power Savings with Adaptive Dimming When Compared to PWM Dimming

V$_{IN}$ = 3.6V
10" Panel
6x7 LED Array
ILED$_{MAX}$ = 23 mA/CH
L = 4.7 µH
1.5 mm Max Height
f$_{SW}$ = 1.25 MHz

POWER SAVINGS [mW] vs BRIGHTNESS [%]
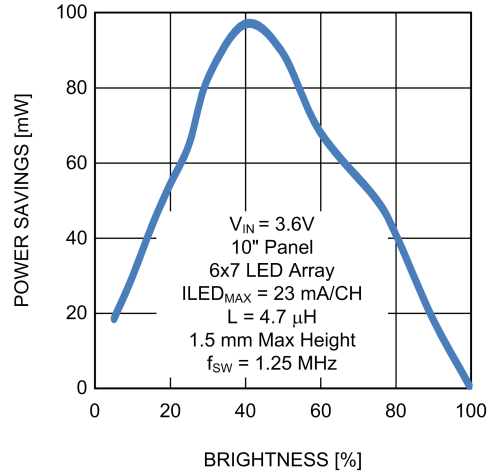
30162659

Steady State Operation Waveforms

V$_{SW}$
20V/DIV

I$_L$
500 mA/DIV

I$_{OUT}$
100 mA/DIV

V$_{BOOSTac}$
200 mV/DIV

1 µs/DIV
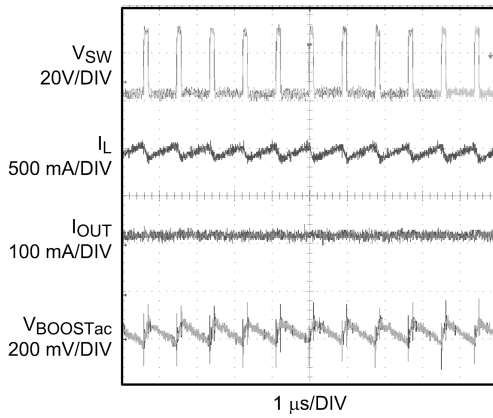
30162660

Start-up Waveforms

EN/V$_{DDIO}$
2V/DIV

V$_{SW}$
20V/DIV

V$_{BOOST}$
20V/DIV

4 ms/DIV

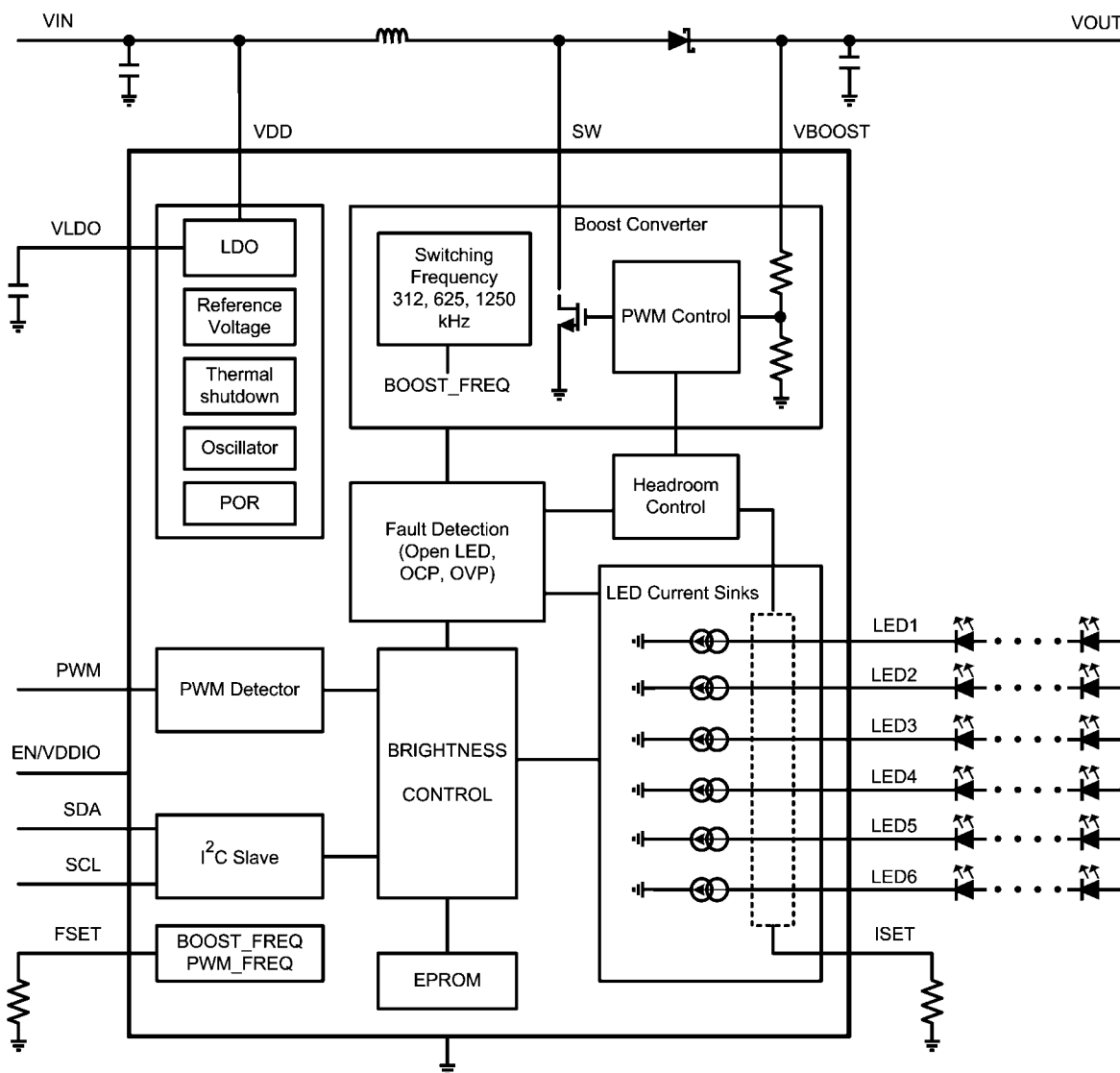30162670

TEXAS
INSTRUMENTS
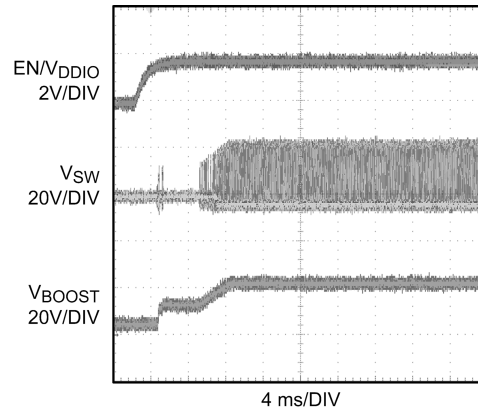
Functional Overview

LP8556 is a white LED driver featuring an asynchronous boost converter and six high precision current sinks that can be controlled by a PWM signal or an I2C master.

The boost converter uses adaptive output voltage control for setting the optimal LED driver voltages as high as 43V. This feature minimizes the power consumption by adjusting the voltage to the lowest sufficient level under all conditions. The converter can operate at three switching frequencies: 312, 625 and 1250 kHz pre-configured via EPROM or settable via an external resistor. Programmable slew rate control and spread spectrum scheme minimize switching noise and improve EMI performance.

LED current sinks can be set with the PWM dimming resolution of up to 15 bits. Proprietary adaptive dimming mode allows higher system power saving. In addition, phase shifted LED PWM dimming allows reduced audible noise and smaller boost output capacitors.

The LP8556 has a full set of safety features that ensure robust operation of the device and external components. The set consists of input under-voltage lockout, thermal shutdown, over-current protection, up to six levels of over-voltage protection, LED open and short detection.

Block Diagram

30162635

FIGURE 2. LP8556 Block Diagram

Boost Converter Overview

OPERATION

The LP8556 boost DC/DC converter generates a 7V to approximately 43V boost output voltage from a 2.7V to 36V boost input voltage. The boost output voltage minimum, maximum value and range can be set digitally by pre-configuring EPROM memory (VBOOST_RANGE, VBOOST and VBOOST_MAX fields).

The converter is a magnetic switching PWM mode DC/DC boost converter with a current limit. It uses CPM (current programmed mode) control, where the inductor current is measured and controlled with the feedback. During startup, the soft-start function reduces the peak inductor current. LP8556 has an internal 20 MHz oscillator which is used for clocking the boost. The following figure shows the boost block diagram.
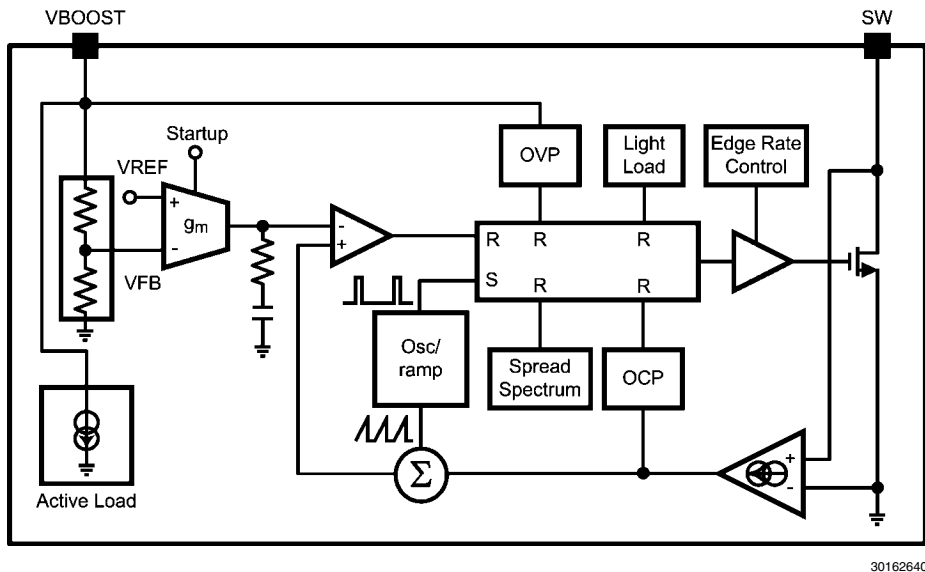

30162640

FIGURE 3. LP8556 Boost Converter Block Diagram

SETTING BOOST SWITCHING FREQUENCY

The LP8556 boost converter switching frequency can be set either by an external resistor (BOOST_FSET_EN = 1 selection), R_{FSET}, or by pre-configuring EPROM memory with the choice of boost frequency (BOOST_FREQ field). *Table 1* summarizes setting of the switching frequency. Note that the R_{FSET} is shared for setting the PWM dimming frequency in addition to setting the boost switching frequency. Setting the boost switching frequency and PWM dimming frequency using an external resistor is separately shown in *Table 5*.

TABLE 1. Configuring Boost Switching Frequency via EPROM

R_{FSET} [Ω]	BOOST_FSET_EN	BOOST_FREQ[1:0]	f_{SW} [kHz]
don't care	0	00	312
don't care	0	01	625
don't care	0	10	1250
don't care	0	11	undefined
(*Note 22*)	1	don't care	(*Note 22*)

Note 22: See *Table 5*

OUTPUT VOLTAGE CONTROL

LP8556 supports two modes of controlling the Boost output voltage, Adaptive Boost Voltage Control and Manual Boost Output Control. Each of the two modes are detailed below.

ADAPTIVE CONTROL:

LP8556 supports a mode of output voltage control called Adaptive Boost Control mode. In this mode, the voltage at the LED pins is periodically monitored by the control loop and adaptively adjusted to the optimum value based on the comparator thresholds set using LED DRIVER_HEADROOM, LED_COMP_HYST, BOOST_STEP_UP, BOOST_STEP_DOWN fields in the EPROM. Settings under LED DRIVER_HEADROOM along with LED_COMP_HYST fields determine optimum boost voltage for a given condition. Boost voltage will be raised if the voltage measured at any of the LED strings falls below the threshold setting determined with LED DRIVER_HEADROOM field. Likewise, boost voltage will be lowered if the voltage measured at any of the LED strings is above the combined setting determined under LED DRIVER_HEADROOM and LED_COMP_HYST fields. LED_COMP_HYST field serves to fine tune the headroom voltage for a given peak LED current. The boost voltage up/down step size can be controlled with the BOOST_STEP_UP and BOOST_STEP_DN fields.

The initial boost voltage is configured with the VBOOST field. This field also sets the minimum boost voltage. The VBOOST_MAX field sets the maximum boost voltage. When an LED pin is open, the monitored voltage will never have enough headroom and the adaptive mode control loop will keep raising the boost voltage. The VBOOST_MAX field allows the boost voltage to be limited to stay under the voltage rating of the external components.

Note: Only LED strings that are enabled are monitored and PS_MODE field determines which LED strings are enabled.

This Adaptive mode is selected using ADAPTIVE bit set to 1 (CFGA EPROM Register) and is the recommended mode of boost control.
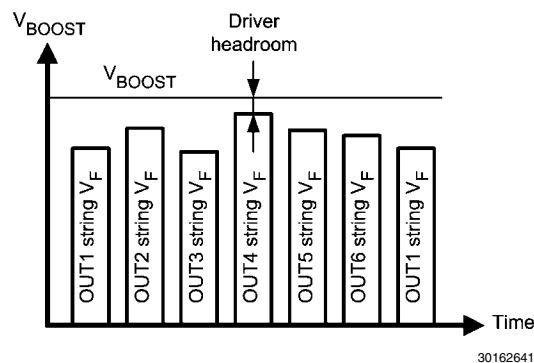
FIGURE 4. Boost Adaptive Control Principle

MANUAL CONTROL:

User can control the boost output voltage with the VBOOST EPROM field when adaptive mode is not used. The following expression shows the relationship between the boost output voltage and the VBOOST field: $V_{BOOST} = V_{BOOST\_MIN} + 0.42*VBOOST[dec]$. The expression is only valid when the calculated values are between the minimum boost output voltage and the maximum boost output voltage. The minimum boost output voltage is set with the VBOOST_RANGE field. The maximum boost output voltage is set with the VBOOST_MAX EPROM field.

EMI REDUCTION

The LP8556 features two EMI reduction schemes.

First scheme, Programmable Slew Rate Control, uses a combination of three drivers for boost switch. Enabling all three drivers allows boost switch on/off transition times to be the shortest. On the other hand, enabling just one driver allows boost switch on/off transition times to be the longest. The longer the transition times, the lower the switching noise on the SW terminal. It should also be noted that the shortest transition times bring the best efficiency as the switching losses are the lowest.

EN_DRV2 and EN_DRV3 bits in the EPROM determine the boost switch driver configuration. Refer to the SW pin slew rate parameter listed under Boost Converter Electrical Characteristics for the slew rate options.

The second EMI reduction scheme is the spread spectrum scheme which deliberately spreads the frequency content of the boost switching waveform, which inherently has a narrow bandwidth, makes the switching waveform's bandwidth wider and ultimately reduces its EMI spectral density.
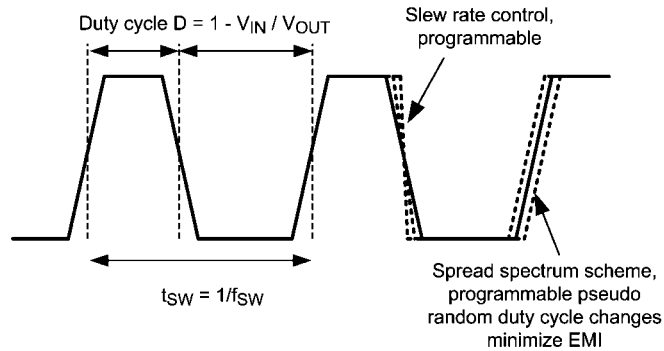
FIGURE 5. Principles of EMI Reduction Schemes

Brightness Control

LP8556 enables various methods of brightness control. The brightness can be controlled using an external PWM signal or the Brightness register accessible by users via an I2C interface or both. How these two input sources are selected and combined is set by the BRT_MODE EPROM bits and described in the following sections, *Figure 6*, and *Table 2*. The LP8556 can also be preconfigured via EPROM memory to allow direct and unaltered brightness control by an external PWM signal. This mode of operation is obtained by setting PWM_DIRECT EPROM bit to '1' (CFG5[7] = 1).

BRT_MODE = 00

With BRT_MODE = 00, the LED output is controlled by the PWM input duty cycle. The PWM detector block measures the duty cycle at the PWM pin and uses this 16-bit value to generate an internal to the device PWM data. Before the output is generated, the PWM data goes through the PWM Curve Shaper block. Then, the data goes into the Adaptive Dimming function which determines the range of the PWM and Current control as described in *OUTPUT DIMMING SCHEMES*. The outcome of the Adaptive Dimming function is 12-bit Current and / or up to 6 PWM output signals. The current is then passed through the non-linear compensation block while the output PWM signals are channeled through the Dither block.

BRT_MODE = 01

With BRT_MODE = 01, the PWM output is controlled by the PWM input duty cycle and the Brightness register. The PWM detector block measures the duty cycle at the PWM pin and uses this 16-bit value to generate the PWM data. Before the output is generated, the PWM data is first multiplied with BRT[7:0] register, then it goes through the PWM Curve Shaper block. Then, the data goes into the Adaptive Dimming function which determines the range of the PWM and Current control as described in *OUTPUT DIMMING SCHEMES* . The outcome of the Adaptive Dimming function is 12-bit Current and / or up to 6 PWM output signals. The current is then passed through the non-linear compensation block while the output PWM signals are channeled through the Dither block.

BRT_MODE = 10

With BRT_MODE = 10, the PWM output is controlled only by the Brightness register. From BRT[7:0] register, the data goes through the PWM Curve Shaper block. Then, the data goes into the Adaptive Dimming function which determines the range of the PWM and Current control as described in *OUTPUT DIMMING SCHEMES* . The outcome of the Adaptive Dimming function is 12-bit Current and / or up to 6 PWM output signals. The current is then passed through the non-linear compensation block while the output PWM signals are channeled through the Dither block.

BRT_MODE = 11

With BRT_MODE = 11, the PWM control signal path is similar to the path when BRT_MODE = 01 except that the PWM input signal is multiplied with BRT[7:0] data after the Curve Shaper block.

TABLE 2. Brightness Control Methods Truth Table

PWM_DIRECT	BRT_MODE [1:0]	Brightness Control Source	Output ILED Form
0	00	External PWM Signal	Adaptive. See *OUTPUT DIMMING SCHEMES*
0	01	External PWM Signal and Brightness Register (multiplied before Curve Shaper)	
0	10	Brightness Register	
0	11	External PWM Signal and Brightness Register (multiplied after Curve Shaper)	
1	don't care	External PWM Signal	Same as the external PWM input
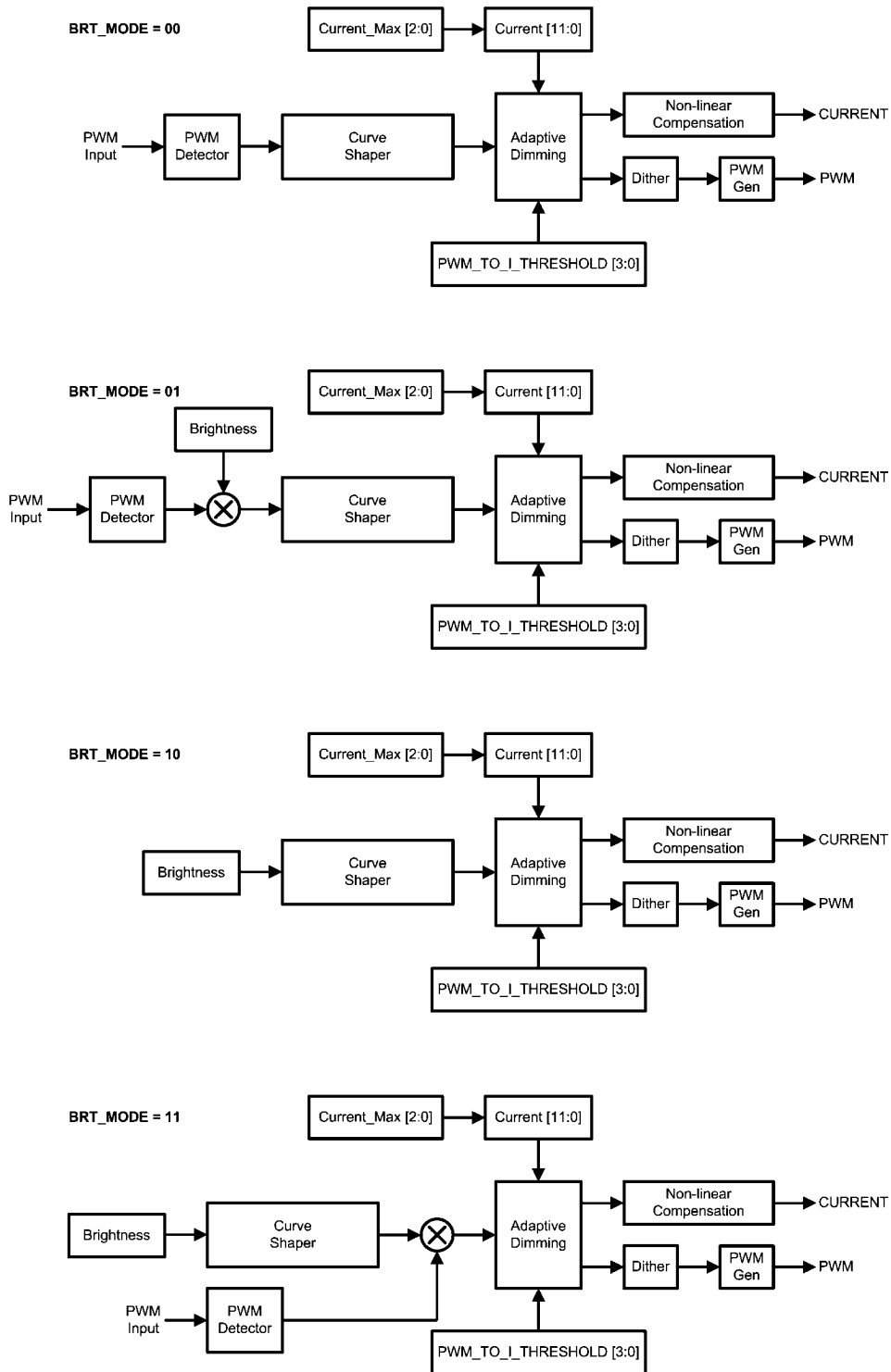
FIGURE 6. Brightness Control Signal Path Block Diagrams

OUTPUT DIMMING SCHEMES

The LP8556 supports three types of output dimming control methods: PWM Control, Pure Current Control and Adaptive Dimming (Hybrid PWM & Current) Control.

PWM Control

PWM control is the traditional way of controlling the brightness using PWM of the outputs with a same LED current across the entire brightness range. Brightness control is achieved by varying the duty cycle proportional to the input PWM. PWM frequency is set either using an external set Resistor (R_{FSET}) or using the PWM_FREQ EPROM field. The maximum LED current is set either using an external set Resistor (R_{ISET}) and CURRENT and CURRENT_MAX EPROM bits or just using the CURRENT and CURRENT_MAX EPROM bits. Note that the output PWM signal is de-coupled and generated independent of the input PWM signal eliminating display flicker issues and allowing better noise immunity
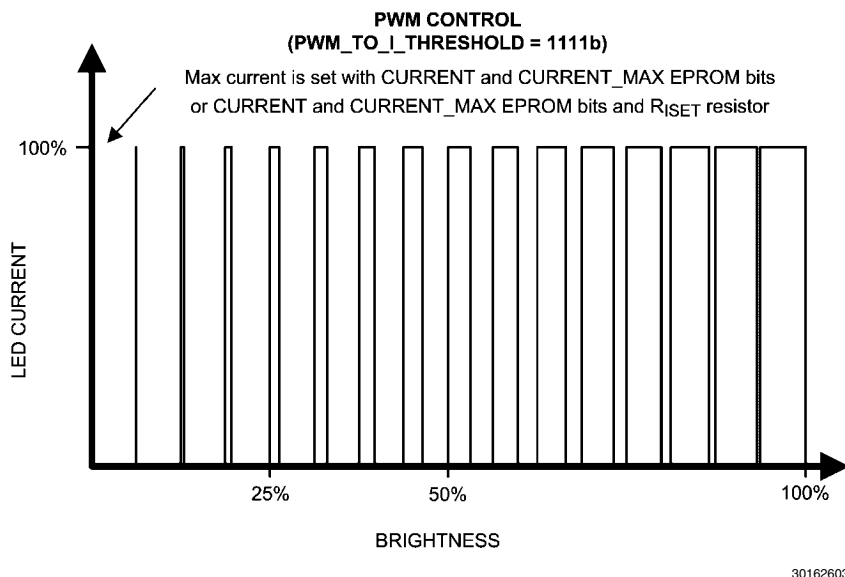
FIGURE 7. PWM Only Output Dimming Scheme

Pure Current Control

In Pure Current Control mode, brightness control is achieved by changing the LED current proportionately from maximum value to a minimum value across the entire brightness range. Like in PWM Control mode, the maximum LED current is set either using an external set Resistor (R_{ISET}) and CURRENT and CURRENT_MAX EPROM bits or just using the CURRENT and CURRENT_MAX EPROM bits. Current resolution in this mode is 12-bits.
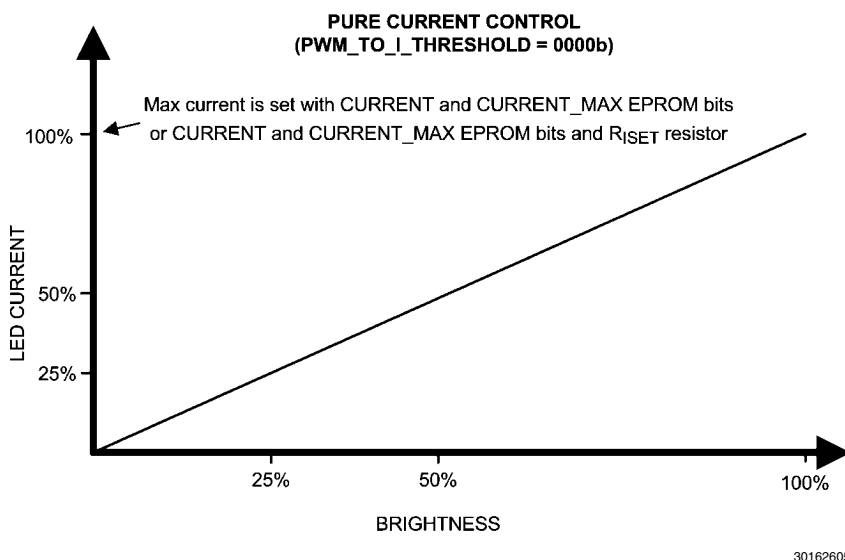
FIGURE 8. Pure Current / Analog Output Dimming Scheme

Adaptive Control

Adaptive dimming control combines PWM Control and Pure Current Control dimming methods. With the adaptive dimming, it is possible to achieve better optical efficiency from the LEDs compared to pure PWM control while still achieving smooth and accurate control at low brightness levels. Current resolution in this mode is 12-bits. Switch point from Current to PWM control can be set with the PWM_TO_I_THRESHOLD EPROM field from 0% to 100% of the brightness range to get good compromise between good matching of the LEDs brightness/white point at low brightness and good optical efficiency.

PWM frequency is set either using an external set Resistor (R_{FSET}) or using the PWM_FREQ EPROM bits. The maximum LED current is set either using an external set Resistor (R_{ISET}) and CURRENT and CURRENT_MAX EPROM bits or just using the CURRENT and CURRENT_MAX EPROM bits.
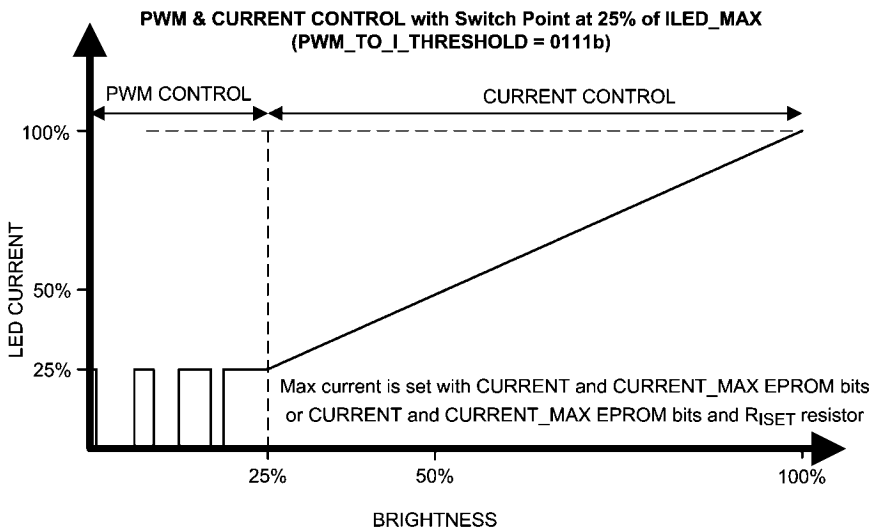
FIGURE 9. Adaptive Output Dimming Scheme

SETTING FULL SCALE LED CURRENT

The maximum or full scale LED current is set either using an external set Resistor (R_{ISET}) and CURRENT and CURRENT_MAX EPROM bits or just using the CURRENT and CURRENT_MAX EPROM bits. Table 3 summarizes setting of the full scale LED current.

TABLE 3. Setting Full Scale LED Current

R_{ISET} [Ω]	ISET_EN	CURRENT_MAX	CURRENT[11:0]	Full Scale ILED [mA]
don't care	0	000	FFFh	5
don't care	0	001	FFFh	10
don't care	0	010	FFFh	15
don't care	0	011	FFFh	20
don't care	0	100	FFFh	23
don't care	0	101	FFFh	25
don't care	0	110	FFFh	30
don't care	0	111	FFFh	50
don't care	0	000 - 111	001h - FFFh	(Note 23)
24k	1	000	FFFh	5
24k	1	001	FFFh	10
24k	1	010	FFFh	15
24k	1	011	FFFh	20
24k	1	100	FFFh	23
24k	1	101	FFFh	25
24k	1	110	FFFh	30
24k	1	111	FFFh	50
12k - 100k	1	000 - 111	001h - FFFh	(Note 23)

Note 23: See CFG0

SETTING PWM DIMMING FREQUENCY

LP8556 PWM dimming frequency can be set either by an external resistor, R_{FSET}, or by pre-configuring EPROM Memory (CFG5 register, PWM_FREQ[3:0] bits). *Table 4* summarizes setting of the PWM dimming frequency. Note that the R_{FSET} is shared for setting the boost switching frequency, too. Setting the boost switching frequency and PWM dimming frequency using an external resistor is shown in *Table 5*.

TABLE 4. Configuring PWM Dimming Frequency via EPROM

R_{FSET} [kΩ]	PWM_FSET_EN	PWM_FREQ[3:0]	f_{PWM} [Hz] (Resolution)
don't care	0	0000	4808 (12-bit)
		0001	6010 (11-bit)
		0010	7212 (11-bit)
		0011	8414 (11-bit)
		0100	9616 (11-bit)
		0101	12020 (10-bit)
		0110	13222 (10-bit)
		0111	14424 (10-bit)
		1000	15626 (10-bit)
		1001	16828 (10-bit)
		1010	18030 (10-bit)
		1011	19232 (10-bit)
		1100	24040 (9-bit)
		1101	28848 (9-bit)
		1110	33656 (9-bit)
		1111	38464 (9-bit)
(*Note 24*)	1	don't care	(*Note 24*)

Note 24: See *Table 5*

TABLE 5. Setting Switching and PWM Dimming Frequency with an External Resistor

R_{FSET} [kΩ] (Tolerance)	f_{SW} [kHz]	f_{PWM} [Hz] (Resolution)
Floating or FSET pin pulled HIGH	1250	9616 (11-bit)
470k - 1M (±5%)	312	2402 (12-bit)
300k, 330k (±5%)	312	4808 (12-bit)
200k (±5%)	312	6010 (11-bit)
147k, 150k, 154k, 158k (±1%)	312	9616 (11-bit)
121k (±1%)	312	12020 (10-bit)
100k (±1%)	312	14424 (10-bit)
86.6k (±1%)	312	16828 (10-bit)
75.0k (±1%)	312	19232 (10-bit)
63.4k (±1%)	625	2402 (12-bit)
52.3k, 53.6k (±1%)	625	4808 (12-bit)
44.2k, 45.3k (±1%)	625	6010 (11-bit)
39.2k (±1%)	625	9616 (11-bit)
34.0k (±1%)	625	12020 (10-bit)
30.1k (±1%)	625	14424 (10-bit)
26.1k (±1%)	625	16828 (10-bit)
23.2k (±1%)	625	19232 (10-bit)
20.5k (±1%)	1250	2402 (12-bit)
18.7k (±1%)	1250	4808 (12-bit)
16.5k (±1%)	1250	6010 (11-bit)
14.7k (±1%)	1250	9616 (11-bit)
13.0k (±1%)	1250	12020 (10-bit)
11.8k (±1%)	1250	14424 (10-bit)
10.7k (±1%)	1250	16828 (10-bit)
9.76k (±1%)	1250	19232 (10-bit)
FSET pin shorted to GND	1250	Same as PWM input

PHASE SHIFT PWM SCHEME

Phase shift PWM scheme allows delaying the time when each LED driver is active. When the LED drivers are not activated simultaneously, the peak load current from the boost output is greatly decreased. This reduces the ripple seen on the boost output and allows smaller output capacitors. Reduced ripple also reduces the output ceramic capacitor audible ringing. PSPWM scheme also increases the load frequency seen on the boost output six times and therefore transfers the possible audible noise to the frequencies outside of the audible range.

Description of the PSPWM mode is seen in the following diagrams. PSPWM mode is set with <PS_MODE[2:0]> bits.

PS_MODE[2:0]	Waveforms	Connection
000		
	6 LED strings with 60 degree phase shift. One driver for each LED string.	
001		
	5 LED strings with 72 degree phase shift. One driver for each LED string. (Driver #6 not used).	
010		
	4 LED strings with 90 degree phase shift. One driver for each LED string. (Drivers #5 and #6 not used).	

011		
	3 LED strings with 120 degree phase shift. One driver for each LED string. (Drivers #4, #5 and #6 not used).	
100		
	2 LED strings with 180 degree phase shift. One driver for each LED string. (Drivers #3, #4, #5 and #6 not used).	
101		
	3 LED strings with 120 degree phase shift. Two drivers for each LED string. (Drivers 1&2, 3&4 and 5&6 are tied and with the same phase).	

110		
	2 LED strings with 180 degree phase shift. Three divers for each LED string. (Drivers 1&2&3 and 4&5&6 are tied and with the same phase).	
111		
	1 LED string driven by all six drivers. (All drivers are tied and with the same phase).	
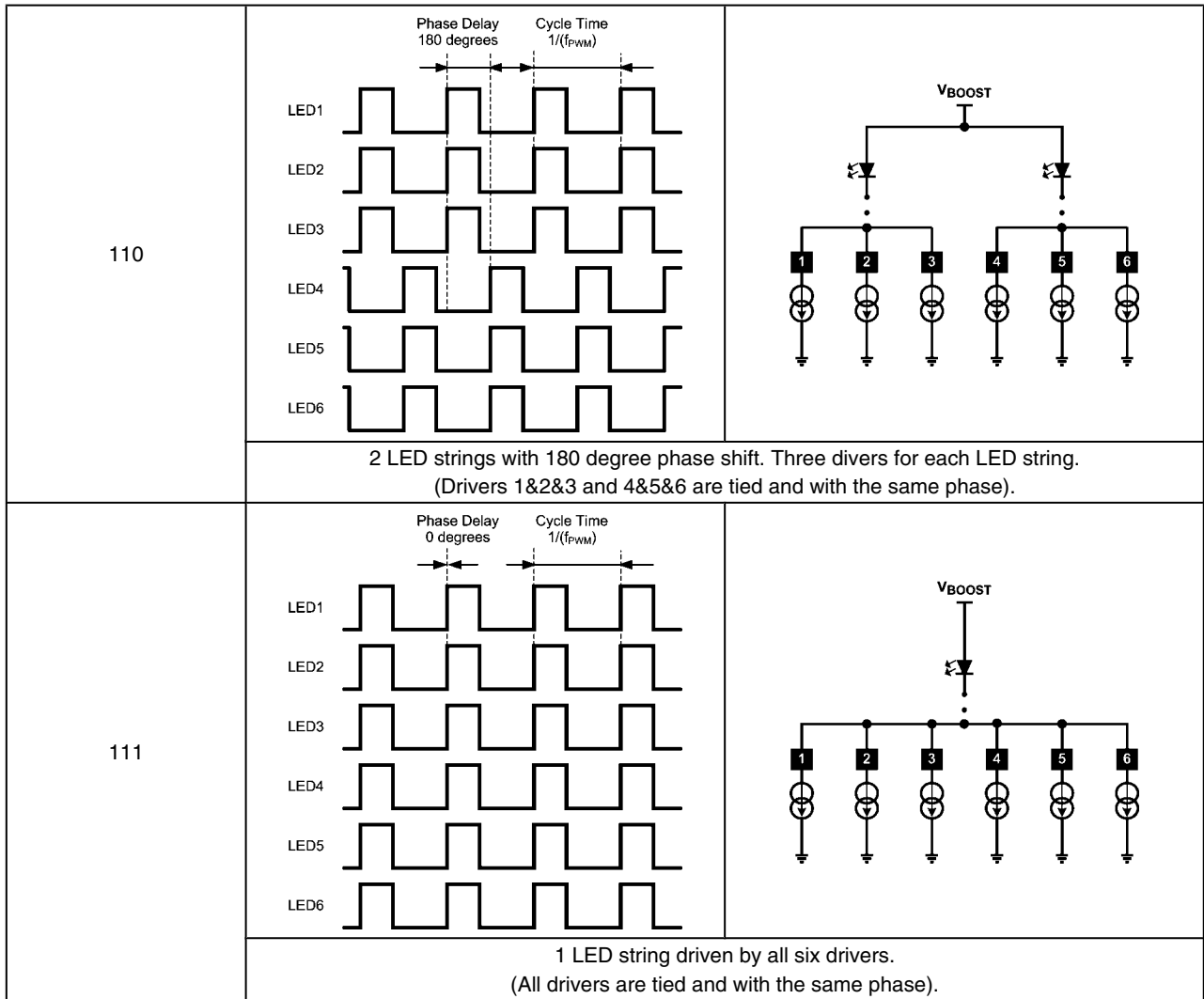
SLOPE AND ADVANCED SLOPE

Transition time between two brightness values can be programmed with EPROM bits <PWM_SLOPE[2:0]> from 0 to 500 ms. Same slope time is used for sloping up and down. With advanced slope the brightness changes can be made more pleasing to a human eye.
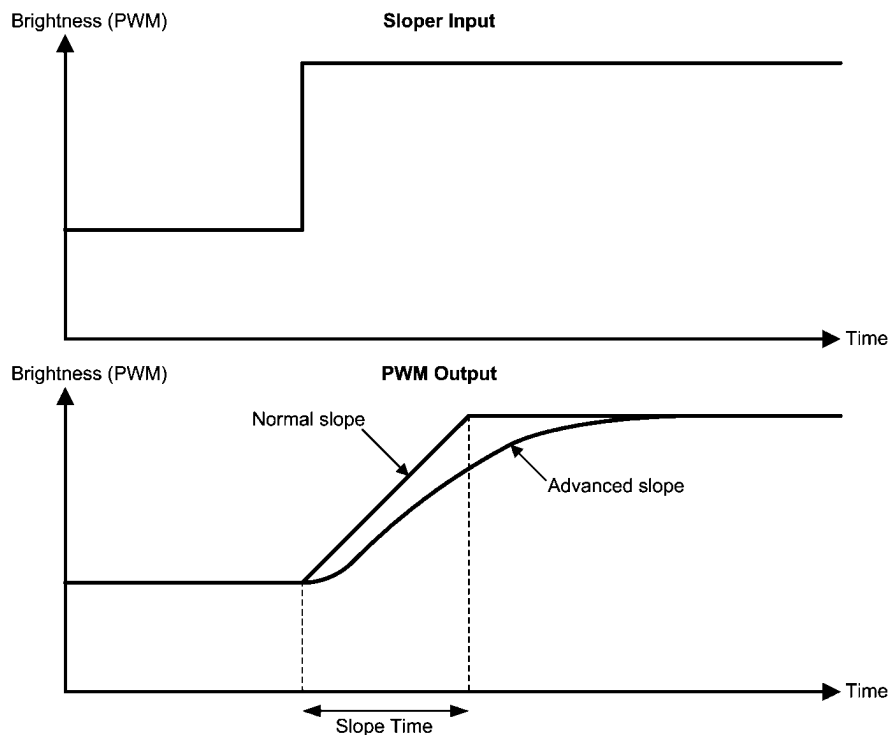
FIGURE 10. Sloper Operation

DITHERING

Special dithering scheme can be used during brightness changes and in steady state condition. It allows increased resolution and smaller average steps size during brightness changes. Dithering can be programmed with EPROM bits <DITHER[1:0]> from 0 to 3 bits. <STEADY_DITHER> EPROM bit sets whether the dithering is used also in steady state or only during slopes. Example below is for 1-bit dithering. E.g. for 3-bit dithering, every 8th pulse is made 1 LSB longer to increase the average value by 1/8th.
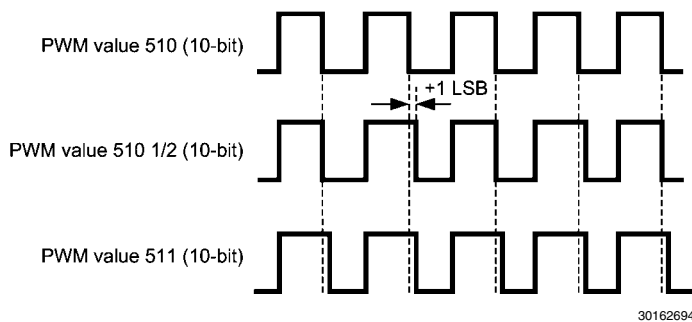
**FIGURE 11. Example of the Dithering,
1-bit dither, 10-bit resolution**

Fault Detection

LP8556 has fault detection for LED open and short conditions, UVLO, over-current and thermal shutdown. The cause for the fault can be read from status register. Reading the fault register will also reset the fault.

LED FAULT DETECTION

With LED fault detection, the voltages across the LED drivers are constantly monitored. Shorted or open LED strings are detected.

OPEN DETECT: The logic uses the LOW comparators and the requested boost voltage to detect the OPEN condition. If the logic is asking the boost for the maximum allowed voltage and a LOW comparator is asserted, then the OPEN bit is set in the STATUS register (ADDR=02h). In normal operation, the adaptive headroom control loop raises the requested boost voltage when the LOW comparator is asserted. If it has raised it as high as it can and an LED string still needs more voltage, then it is assumed to be disconnected from the boost voltage (open or grounded). The actual boost voltage is not part of the OPEN condition decision; only the requested boost voltage and the LOW comparators.

SHORT DETECT: The logic uses all three comparators (HIGH, MID and LOW) to detect the SHORT condition. When the MID and LOW comparators are de-asserted, the headroom control loop considers that string to be optimized - enough headroom, but not excessive. If at least one LED string is optimized and at least one other LED string has its HIGH comparator asserted, then the SHORT condition is detected. It is important to note that the SHORT condition requires at least two strings for detection: one in the optimized headroom zone (LOW/MID/HIGH comparators all de-asserted) and one in the excessive headroom zone (HIGH comparator asserted).

Fault is cleared by reading the fault register.

UNDER-VOLTAGE DETECTION

LP8556 has detection for too-low VIN voltage. Threshold level for the voltage is set with EPROM register bits as shown in the following table:

TABLE 6. UVLO Truth Table

UVLO_EN	UVLO_TH	Threshold (V)
0	don't care	OFF
1	0	2.5V
1	1	5.2V

When under voltage is detected the LED outputs and the boost will shutdown and the corresponding fault bit is set in the fault register. The LEDs and the boost will start again when the voltage has increased above the threshold level. Hysteresis is implemented to threshold level to avoid continuous triggering of fault when threshold is reached.

Fault is cleared by setting the EN / VDDIO pin low or by reading the fault register.

OVER-CURRENT PROTECTION

LP8556 has detection for too-high loading on the boost converter. When over-current fault is detected, the the boost will shutdown and the corresponding fault bit is set in the fault register. The boost will start again when the current has dropped below the OCP threshold.

Fault is cleared by reading the fault register.

THERMAL SHUTDOWN

If the LP8556 reaches thermal shutdown temperature (150 °C) the LED outputs and boost will shut down to protect it from damage. Device will re-activate again when temperature drops below 130 °C degrees.

Fault is cleared by reading the fault register.

I2C Compatible Serial Bus Interface

INTERFACE BUS OVERVIEW

The I2C-compatible synchronous serial interface provides access to the programmable functions and registers on the device. This protocol uses a two-wire interface for bidirectional communications between the IC's connected to the bus. The two interface lines are the Serial Data Line (SDA) and the Serial Clock Line (SCL). These lines should be connected to a positive supply via a pull-up resistor and remain HIGH even when the bus is idle.

Every device on the bus is assigned a unique address and acts as either a Master or a Slave depending on whether it generates or receives the SCL. The LP8556 can operate as an I2C slave.

DATA TRANSACTIONS

One data bit is transferred during each clock pulse. Data is sampled during the high state of the serial clock SCL. Consequently, throughout the clock's high period, the data should remain stable. Any changes on the SDA line during the high state of the SCL and in the middle of a transaction, aborts the current transaction. New data should be sent during the low SCL state. This protocol permits a single data line to transfer both command/control information and data using the synchronous serial clock.
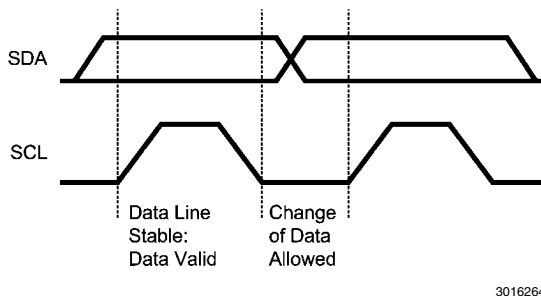
FIGURE 12. Bit Transfer

Each data transaction is composed of a Start Condition, a number of byte transfers (set by the software) and a Stop Condition to terminate the transaction. Every byte written to the SDA bus must be 8 bits long and is transferred with the most significant bit first. After each byte, an Acknowledge signal must follow. The following sections provide further details of this process.
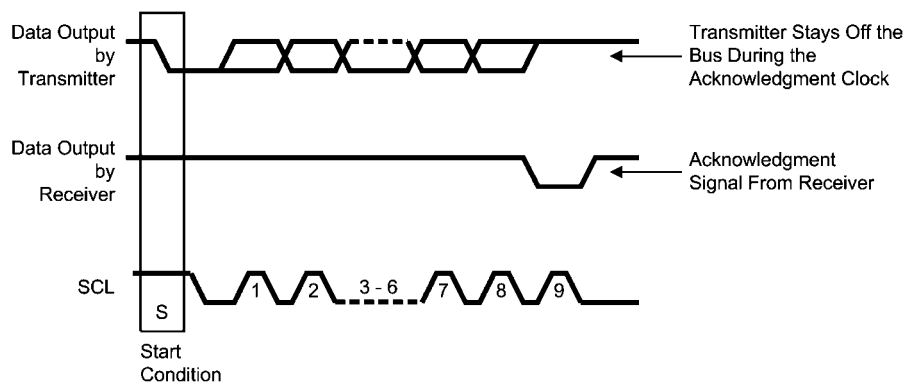
FIGURE 13. Start and Stop

The Master device on the bus always generates the Start and Stop Conditions (control codes). After a Start Condition is generated, the bus is considered busy and it retains this status until a certain time after a Stop Condition is generated. A high-to-low transition of the data line (SDA) while the clock (SCL) is high indicates a Start Condition. A low-to-high transition of the SDA line while the SCL is high indicates a Stop Condition.

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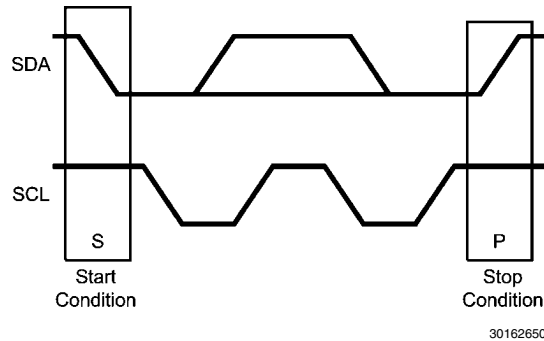
FIGURE 14. Start and Stop Conditions

In addition to the first Start Condition, a repeated Start Condition can be generated in the middle of a transaction. This allows another device to be accessed, or a register read cycle.

ACKNOWLEDGE CYCLE

The Acknowledge Cycle consists of two signals: the acknowledge clock pulse the master sends with each byte transferred, and the acknowledge signal sent by the receiving device.

The master generates the acknowledge clock pulse on the ninth clock pulse of the byte transfer. The transmitter releases the SDA line (permits it to go high) to allow the receiver to send the acknowledge signal. The receiver must pull down the SDA line during the acknowledge clock pulse and ensure that SDA remains low during the high period of the clock pulse, thus signaling the correct reception of the last data byte and its readiness to receive the next byte.

"ACKNOWLEDGE AFTER EVERY BYTE" RULE

The master generates an acknowledge clock pulse after each byte transfer. The receiver sends an acknowledge signal after every byte received.

There is one exception to the "acknowledge after every byte" rule. When the master is the receiver, it must indicate to the transmitter an end of data by not-acknowledging ("negative acknowledge") the last byte clocked out of the slave. This "negative acknowledge" still includes the acknowledge clock pulse (generated by the master), but the SDA line is not pulled down.

ADDRESSING TRANSFER FORMATS

Each device on the bus has a unique slave address. The LP8556 operates as a slave device with 7-bit address combined with data direction bit. Slave address is 2Ch as 7-bit or 58h for write and 59h for read in 8-bit format.

Before any data is transmitted, the master transmits the the slave I.D. The slave device should send an acknowledge signal on the SDA line, once it recognizes its address.

The slave address is the first seven bits after a Start Condition. The direction of the data transfer (R/W) depends on the bit sent after the slave address — the eighth bit.

When the slave address is sent, each device in the system compares this slave address with its own. If there is a match, the device considers itself addressed and sends an acknowledge signal. Depending upon the state of the R/W bit (1:read, 0:write), the device acts as a transmitter or a receiver.

MSB							LSB
ADR6 Bit7	ADR5 bit6	ADR4 bit5	ADR3 bit4	ADR2 bit3	ADR1 bit2	ADR0 bit1	R/W bit0
x	x	x	x	x	x	x	

◄──────── I²C SLAVE address (chip address) ────────►

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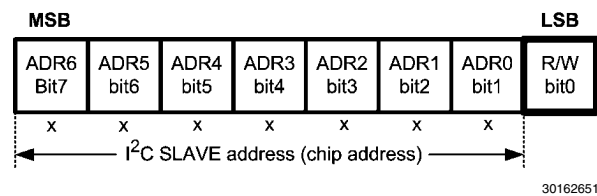
FIGURE 15. I²C Chip Address (0x2C)

Control Register Write Cycle

• Master device generates start condition.
• Master device sends slave address (7 bits) and the data direction bit (r/w = 0).
• Slave device sends acknowledge signal if the slave address is correct.
• Master sends control register address (8 bits).
• Slave sends acknowledge signal.
• Master sends data byte to be written to the addressed register.
• Slave sends acknowledge signal.
• If master will send further data bytes the control register address will be incremented by one after acknowledge signal.
• Write cycle ends when the master creates stop condition.

Control Register Read Cycle

- Master device generates a start condition.
- Master device sends slave address (7 bits) and the data direction bit (r/w = 0).
- Slave device sends acknowledge signal if the slave address is correct.
- Master sends control register address (8 bits).
- Slave sends acknowledge signal.
- Master device generates repeated start condition.
- Master sends the slave address (7 bits) and the data direction bit (r/w = 1).
- Slave sends acknowledge signal if the slave address is correct.
- Slave sends data byte from addressed register.
- If the master device sends acknowledge signal, the control register address will be incremented by one. Slave device sends data byte from addressed register.
- Read cycle ends when the master does not generate acknowledge signal after data byte and generates stop condition.

TABLE 7. Data Read and Write Cycles

	Address Mode
Data Read	\<Start Condition\> \<Slave Address\>\<r/w = 0\>[Ack] \<Register Addr.\>[Ack] \<Repeated Start Condition\> \<Slave Address\>\<r/w = 1\>[Ack] [Register Data]\<Ack or NAck\> … additional reads from subsequent register address possible \<Stop Condition\>
Data Write	\<Start Condition\> \<Slave Address\>\<r/w='0'\>[Ack] \<Register Addr.\>[Ack] \<Register Data\>[Ack] … additional writes to subsequent register address possible \<Stop Condition\>

\<\>Data from master [ ] Data from slave

Register Read and Write Detail
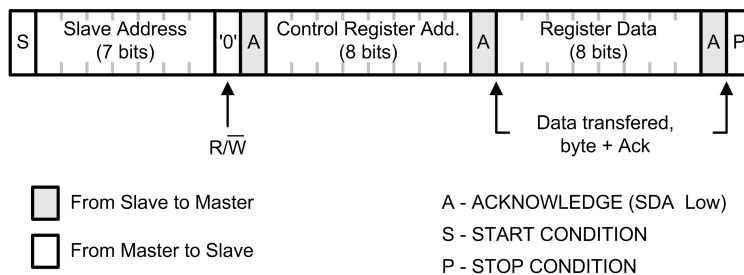
Register Write Format

30162647

FIGURE 16. Register Write Format
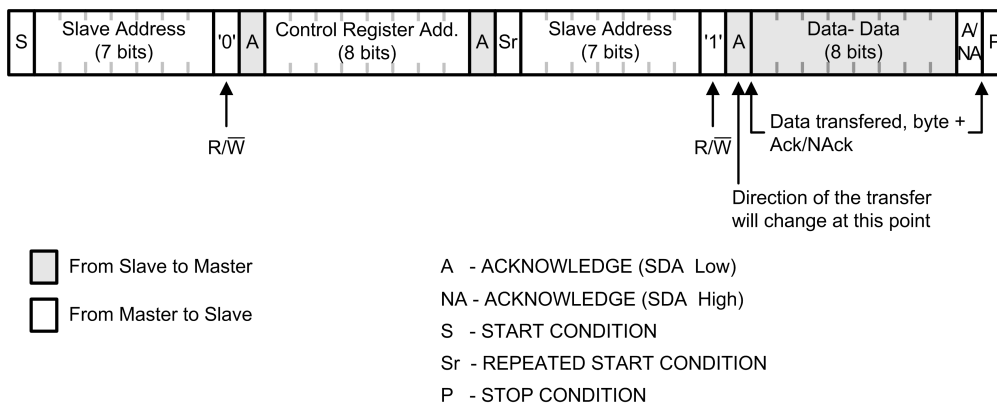
Register Read Format

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FIGURE 17. Register Read Format

Register Map

ADDR	REGISTER	D7	D6	D5	D4	D3	D2	D1	D0	RESET
00H	Brightness Control	BRT[7:0]								0000 0000
01H	Device Control	FAST					BRT_MODE		BL_CTL	0000 0000
02H	Status	OPEN	SHORT	VREF_OK	VBOOST_OK	OVP	OCP	TSD	UVLO	0000 0000
03H	ID	PANEL	MFG					REV		1111 1100
04H	Direct Control	LED								0000 0000
16H	LED Enable	LED_EN								0011 1111

EPROM Memory Map

ADDR	REGISTER	D7	D6	D5	D4	D3	D2	D1	D0
98H	CFG98	IBOOST_LIM_2X	RESERVED	RESERVED	RESERVED	RESERVED	RESERVED	RESERVED	RESERVED
9EH	CFG9E	RESERVED	VBOOST_RANGE	VBOOST_RANGE	RESERVED	HEADROOM_OFFSET	HEADROOM_OFFSET	HEADROOM_OFFSET	HEADROOM_OFFSET
A0H	CFG0	CURRENT LSB	CURRENT LSB	CURRENT LSB	CURRENT LSB	CURRENT LSB	CURRENT LSB	CURRENT LSB	CURRENT LSB
A1H	CFG1	PDET_STDBY	CURRENT_MAX	CURRENT_MAX	CURRENT_MAX	CURRENT_MAX	CURRENT MSB	CURRENT MSB	CURRENT MSB
A2H	CFG2	RESERVED	RESERVED	UVLO_EN	UVLO_TH	BL_ON	ISET_EN	BOOST_FSET_EN	PWM_FSET_EN
A3H	CFG3	RESERVED	RESERVED	SLOPE	RESERVED	RESERVED	FILTER	PWM_INPUT_HYSTERESIS	PWM_INPUT_HYSTERESIS
A4H	CFG4	PWM_TO_I_THRESHOLD	PWM_TO_I_THRESHOLD	PWM_TO_I_THRESHOLD	PWM_TO_I_THRESHOLD	RESERVED	STEADY_DITHER	DITHER	DITHER
A5H	CFG5	PWM_DIRECT	RESERVED	PS_MODE	PS_MODE	PWM_FREQ	PWM_FREQ	PWM_FREQ	PWM_FREQ
A6H	CFG6	BOOST_FREQ	BOOST_FREQ	VBOOST	VBOOST	VBOOST	VBOOST	VBOOST	VBOOST
A7H	CFG7	RESERVED	RESERVED	EN_DRV3	EN_DRV2	RESERVED	RESERVED	IBOOST_LIM	IBOOST_LIM
A8H	CFG8	RESERVED	RESERVED	RESERVED	RESERVED	RESERVED	RESERVED	RESERVED	RESERVED
A9H	CFG9	VBOOST_MAX	VBOOST_MAX	VBOOST_MAX	JUMP_EN	JUMP_THRESHOLD	JUMP_THRESHOLD	JUMP_VOLTAGE	JUMP_VOLTAGE
AAH	CFGA	SSCLK_EN	RESERVED	RESERVED	RESERVED	ADAPTIVE	DRIVER_HEADROOM	DRIVER_HEADROOM	DRIVER_HEADROOM
ABH	CFGB	RESERVED	RESERVED	RESERVED	RESERVED	RESERVED	RESERVED	RESERVED	RESERVED
ACH	CFGC	RESERVED	RESERVED	RESERVED	RESERVED	RESERVED	RESERVED	RESERVED	RESERVED
ADH	CFGD	RESERVED	RESERVED	RESERVED	RESERVED	RESERVED	RESERVED	RESERVED	RESERVED
AEH	CFGE	STEP_UP	STEP_UP	STEP_DN	STEP_DN	LED_FAULT_TH	LED_FAULT_TH	LED_COMP_HYST	LED_COMP_HYST
AFH	CFGF	REVISION	REVISION	REVISION	REVISION	REVISION	REVISION	REVISION	REVISION

Register Bit Explanations

BRIGHTNESS CONTROL

Address 00h

Reset value 0000 0000b

Brightness Control register							
7	6	5	4	3	2	1	0
BRT[7:0]							
Name	Bit	Access	Description				
BRT	7:0	R/W	Backlight PWM 8-bit linear control.				

DEVICE CONTROL

Address 01h

Reset value 0000 0000b

Device Control register							
7	6	5	4	3	2	1	0
FAST					BRT_MODE[1:0]		BL_CTL
Name	Bit	Access	Description				
FAST	7		Skip refresh of trim and configuration registers from EPROMs when exiting the low power STANDBY mode. 0 = read EPROMs before returning to the ACTIVE state 1 = only read EPROMs once on initial power-up.				
BRT_MODE	2:1	R/W	Brightness source mode *Figure 6* 00b = PWM input only 01b = PWM input and Brightness register (combined before shaper block) 10b = Brightness register only 11b = PWM input and Brightness register (combined after shaper block)				
BL_CTL	0	R/W	Enable backlight when Brightness Register is used to control brightness (BRT_MODE = 10). 0 = Backlight disabled and chip turned off 1 = Backlight enabled and chip turned on This bit has no effect when PWM pin control is selected for brightness control (BRT_MODE = 00). In this mode the state of PWM pin enable or disables the chip.				

STATUS

Address 02h

Reset value 0000 0000b

Fault register							
7	6	5	4	3	2	1	0
OPEN	SHORT	VREF_OK	VBOOST_OK	OVP	OCP	TSD	UVLO

Name	Bit	Access	Description
OPEN	7	R	LED open fault detection 0 = No fault 1 = LED open fault detected. The value is not latched.
SHORT	6	R	LED short fault detection 0 = No fault 1 = LED short fault detected. The value is not latched.
VREF_OK	5	R	Internal VREF node monitor status 1 = VREF voltage is OK.
VBOOST_OK	4	R	Boost output voltage monitor status 0 = Boost output voltage has not reached its target (VBOOST < Vtarget - 2.5V) 1 = Boost output voltage is OK. The value is not latched.
OVP	3	R	Overvoltage protection 0 = No fault 1 = Overvoltage condition occurred. Fault is cleared by reading the register 02h.
OCP	2	R	Over current protection 0 = No fault 1 = Over current detected in boost output. OCP detection block monitors the boost output and if the boost output has been too low for more than 50 ms it will generate OCP fault and disable the boost. Fault is cleared by reading the register 02h. After clearing the fault boost will startup again.
TSD	1	R	Thermal shutdown 0 = No fault 1 = Thermal fault generated, 150 °C reached. Boost converter and LED outputs will be disabled until the temperature has dropped down to 130 °C. Fault is cleared by reading this register.
UVLO	0	R	Under voltage detection 0 = No fault 1 = Under voltage detected on the V_{DD} pin. Boost converter and LED outputs will be disabled until V_{DD} voltage is above the UVLO threshold voltage. Threshold voltage is set with EPROM bits. Fault is cleared by reading this register.

IDENTIFICATION

Address 03h

Reset value 1111 1100b

Identification register							
7	6	5	4	3	2	1	0
PANEL	MFG[3:0]				REV[2:0]		

Name	Bit	Access	Description
PANEL	7	R	Panel ID code
MFG	6:3	R	Manufacturer ID code
REV	2:0	R	Revision ID code

DIRECT CONTROL

Address 04h

Reset value 0000 0000b

Direct Control register							
7	6	5	4	3	2	1	0
		OUT[5:0]					

Name	Bit	Access	Description
OUT	5:0	R/W	Direct control of the LED outputs 0 = Normal operation. LED output are controlled with the adaptive dimming block 1 = LED output is forced to 100% PWM.

LED String Enable

Address 16h

Reset value 0011 1111b

Temp LSB register							
7	6	5	4	3	2	1	0
		LED_EN[5:0]					

Name	Bit	Access	Description
LED_EN	5:0	R/W	Bits 5:0 correspond to LED Strings 6:1 respectively. Bit value 1 = LED String Enabled Bit value 0 = LED String Disabled Note: To disable string(s), it is recommended to disable higher order string(s). For example, - for 5 String configuration, disable 6th String. - for 4 string configuration, disable 6th and 5th string. These bits are ANDed with the internal LED enable bits that are generated with the PS_MODE logic.

EPROM Bit Explanations

LP8556TM (Micro SMD) Configurations and Pre-configured EPROM Settings

ADDRESS	LP8556-E00	LP8556-E01	LP8556-E02	LP8556-E03	LP8556-E04	LP8556-E05 (*Note 25*)
98h[7]	0b	0b	0b	0b	0b	0b
9Eh	22h	22h	22h	24h	24h	22h
A0h	FFh	FFh	FFh	FFh	FFh	
A1h	CFh	4Fh	5Fh	BFh	3Fh	
A2h	2Fh	20h	20h	28h	2Fh	
A3h	5Eh	03h	5Eh	5Eh	5Eh	
A4h	72h	12h	72h	72h	72h	
A5h	14h	0Ch	04h	14h	04h	
A6h	80h	80h	80h	80h	80h	
A7h	FFh	FFh	FFh	FFh	FFh	
A8h	00h	00h	00h	00h	00h	
A9h	A0h	80h	80h	A0h	60h	
AAh	0Fh	0Fh	0Fh	0Fh	0Fh	
ABh	00h	00h	00h	00h	00h	
ACh	00h	00h	00h	00h	00h	
ADh	00h	00h	00h	00h	00h	
AEh	0Fh	0Fh	0Fh	0Fh	0Fh	
AFh	02h	02h	04h	02h	02h	

Note 25: LP8556-E05 is a device option with un-configured EPROM settings. This option is for users that desire programming the device by themselves. Bits 98h[7] and 9Eh[5] are always pre-configured.

LP8556TM (Micro SMD) Configurations and Pre-configured EPROM Settings Continued

ADDRESS	LP8556-E06	LP8556-E07	LP8556-E08	LP8556-E09	LP8556-E10	LP8556-E11
98h[7]	0b	0b	0b	0b	0b	
9Eh	22h	04h	22h	22h	24h	
A0h	FFh	FFh	FFh	FFh	EBh	
A1h	DBh	BFh	CFh	CFh	3Dh	
A2h	2Fh	0Dh	2Fh	2Fh	2Fh	
A3h	02h	02h	5Eh	02h	37h	
A4h	72h	72h	72h	72h	77h	
A5h	14h	20h	24h	04h	1Bh	
A6h	40h	4Eh	80h	80h	40h	
A7h	FFh	FEh	FFh	FFh	FEh	
A8h	21h	21h	00h	00h	21h	
A9h	DBh	C0h	A0h	A0h	9Bh	
AAh	0Fh	0Fh	0Fh	0Fh	3Fh	
ABh	00h	00h	00h	00h	00h	
ACh	00h	00h	00h	00h	00h	
ADh	00h	00h	00h	00h	00h	
AEh	0Fh	0Fh	0Fh	0Fh	0Fh	
AFh	02h	02h	02h	03h	00h	

LP8556SQ (LLP) Configurations and Pre-configured EPROM Settings

ADDRESS	LP8556-E00	LP8556-E08	LP8556-E09
98h[7]	1b	1b	1b
9Eh	22h	22h	22h
A0h	FFh	FFh	FFh
A1h	CFh	CFh	CFh
A2h	2Fh	2Fh	2Fh
A3h	5Eh	5Eh	02h
A4h	72h	72h	72h
A5h	14h	24h	04h
A6h	80h	80h	80h
A7h	FEh	FEh	FEh
A8h	00h	00h	00h
A9h	A0h	A0h	A0h
AAh	0Fh	0Fh	0Fh
ABh	00h	00h	00h
ACh	00h	00h	00h
ADh	00h	00h	00h
AEh	0Fh	0Fh	0Fh
AFh	00h	00h	00h

CFG98

Address 98h

CFG98 register

7	6	5	4	3	2	1	0
IBOOST_LIM_2X							

Name	Bit	Access	Description
IBOOST_LIM_2X	7	R/W	Select the inductor current limit range. When IBOOST_LIM_2X = 0, the inductor current limit can be set to 0.9A, 1.2A, 1.5A or 1.8A. When IBOOST_LIM_2X = 1, the inductor current limit can be set to 1.6A, 2.1A, or 2.6A . This option is supported only on LLP package and not on Micro SMD package. See (*Note 11*).

CFG9E

Address 9Eh

CFG9E register

7	6	5	4	3	2	1	0
		VBOOST_RANGE			HEADROOM_OFFSET		

Name	Bit	Access	Description
VBOOST_RANGE	5	R/W	Select VBOOST range. When VBOOST_RANGE = 0, the output voltage range is from 7V to 34V When VBOOST_RANGE = 1, the output voltage range is from 16V to 43V
HEADROOM_OFFSET	3:0	R/W	LED driver headroom offset. This adjusts the LOW comparator threshold together with LED_HEADROOM bits and contributes to the MID comparator threshold. 0000 = 460 mV 0001 = 390 mV 0010 = 320 mV 0100 = 250 mV 1000 = 180 mV

CFG0

Address A0h

CFG0 register							
7	6	5	4	3	2	1	0
CURRENT LSB[7:0]							

Name	Bit	Access	Description		
CURRENT LSB	7:0	R/W	The 8-bits in this register (LSB) along the 4-bits defined in CFG1 Register (MSB) allow LED current to be set in 12-bit fine steps. These 12-bits further scale the maximum LED current set using CFG1 Register, CURRENT_MAX bits (denoted as IMAX). If ISET_EN = 0, the LED current is defined with the bits as shown below. If ISET_EN = 1, then the external resistor connected to the ISET pin scales the LED current as shown below.		
				ISET_EN = 0	ISET_EN = 1
			0000 0000 0000	0A	0A
			0000 0000 0001	$(1/4095) \times I_{MAX}$	$(1/4095) \times I_{MAX} \times 20000 \times 1.2V / R_{ISET}$
			0000 0000 0010	$(2/4095) \times I_{MAX}$	$(2/4095) \times I_{MAX} \times 20000 \times 1.2V / R_{ISET}$
			...	...	...
			0111 1111 1111	$(2047/4095) \times I_{MAX}$	$(2047/4095) \times I_{MAX} \times 20000 \times 1.2V / R_{ISET}$
			...	...	...
			1111 1111 1101	$(4093/4095) \times I_{MAX}$	$(4093/4095) \times I_{MAX} \times 20000 \times 1.2V / R_{ISET}$
			1111 1111 1110	$(4094/4095) \times I_{MAX}$	$(4094/4095) \times I_{MAX} \times 20000 \times 1.2V / R_{ISET}$
			1111 1111 1111	$(4095/4095) \times I_{MAX}$	$(4095/4095) \times I_{MAX} \times 20000 \times 1.2V / R_{ISET}$

CFG1

Address A1h

CFG1 register							
7	6	5	4	3	2	1	0
PDET_STDBY	CURRENT_MAX[2:0]			CURRENT MSB[11:8]			

Name	Bit	Access	Description
PDET_STDBY	7	R/W	Enable Standby when PWM input is constant low (approx. 50 ms timeout).
CURRENT_MAX	6:4	R/W	Set Maximum LED current as shown below. This maximum current is scaled as described in the CFG0 Register. 000 = 5 mA 001 = 10 mA 010 = 15 mA 011 = 20 mA 100 = 23 mA 101 = 25 mA 110 = 30 mA 111 = 50 mA
CURRENT MSB	3:0	R/W	These bits form the 4 MSB bits for LED Current as described in CFG0 Register

CFG2

Address A2h

CFG2 register

7	6	5	4	3	2	1	0
RESERVED		UVLO_EN	UVLO_TH	BL_ON	ISET_EN	BOOST_ _FSET_EN	PWM_ _FSET_EN

Name	Bit	Access	Description
RESERVED	7:6	R/W	
UVLO_EN	5	R/W	Undervoltage lockout protection enable.
UVLO_TH	4	R/W	UVLO threshold levels: 0 = 2.5V 1 = 5.2V
BL_ON	3	R/W	Enable backlight. This bit must be set for PWM only control. 0 = Backlight disabled. This selection is recommended for systems with an I2C master. With an I2C master, the backlight can be controlled by writing to the register 01h. 1 = Backlight enabled. This selection is recommended for systems with PWM only control.
ISET_EN	2	R/W	Enable LED current set resistor. 0 = Resistor is disabled and current is set with CURRENT and CURRENT_MAX EPROM register bits. 1 = Resistor is enabled and current is set with the R_{ISET} resistor AND CURRENT AND CURRENT_MAX EPROM register bits.
BOOST_FSET_EN	1	R/W	Enable configuration of the switching frequency via FSET pin. 0 = Configuration of the switching frequency via FSET pin is is disabled. The switching frequency is set with BOOST_FREQ EPROM register bits. 1 = Configuration of the switching frequency via FSET pin is is enabled.
PWM_FSET_EN	0	R/W	Enable configuration of the PWM dimming frequency via FSET pin. 0 = Configuration of the switching frequency via FSET pin is is disabled. The switching frequency is set with PWM_FREQ EPROM register bits. 1 = Configuration of the PWM dimming frequency via FSET pin is is enabled.

CFG3

Address A3h

CFG3 register							
7	6	5	4	3	2	1	0
RESERVED	SLOPE[2:0]			FILTER[1:0]		PWM_INPUT_HYSTERESIS [1:0]	

Name	Bit	Access	Description
RESERVED	7	R/W	
SLOPE	6:4	R/W	Select brightness change transition duration 000 = 0 ms (immediate change) 001 = 1 ms 010 = 2 ms 011 = 50 ms 100 = 100 ms 101 = 200 ms 110 = 300 ms 111 = 500 ms
FILTER	3:2	R/W	Select brightness change transition filtering strength 00 = No filtering. 01 = light smoothing 10 = medium smoothing 11 = heavy smoothing
PWM_INPUT_ _HYSTERESIS	1:0	R/W	PWM input hysteresis function. 00 = OFF 01 = 1-bit hysteresis with 13-bit resolution 10 = 1-bit hysteresis with 12-bit resolution 11 = 1-bit hysteresis with 8-bit resolution

CFG4

Address A4h

CFG4 register

7	6	5	4	3	2	1	0
PWM_TO_I_THRESHOLD[3:0]				RESERVED	STEADY__DITHER	DITHER[1:0]	

Name	Bit	Access	Description
PWM_TO_I__THRESHOLD	7:4	R/W	Select switch point between PWM and pure current dimming 0000 = current dimming across entire range 0001 = switch point at **10%** of the maximum LED current. 0010 = switch point at **12.5%** of the maximum LED current. 0011 = switch point at **15%** of the maximum LED current. 0100 = switch point at **17.5%** of the maximum LED current. 0101 = switch point at **20%** of the maximum LED current. 0110 = switch point at **22.5%** of the maximum LED current. 0111 = switch point at **25%** of the maximum LED current. This is a recommended selection. 1000 = switch point at **33.33%** of the maximum LED current. 1001 = switch point at **41.67%** of the maximum LED current. 1010 = switch point at **50%** of the maximum LED current. 1011 to 1111 = PWM dimming across entire range
RESERVED	3	R/W	
STEADY_DITHER	2	R/W	Dither function method select: 0 = Dither only on transitions 1 = Dither at all times
DITHER	1:0	R/W	Dither function control 00 = Dithering disabled 01 = 1-bit dithering 10 = 2-bit dithering 11 = 3-bit dithering

CFG5

Address A5h

CFG5 register

7	6	5	4	3	2	1	0
PWM_DIRECT		PS_MODE[2:0]			PWM_FREQ[3:0]		

Name	Bit	Access	Description
PWM_DIRECT	7	R/W	Intended for certain test mode purposes. When enabled, the entire pipeline is bypassed and PWM output is connected with PWM input.
PS_MODE	6:4	R/W	Select PWM output phase configuration: 000 = 6-phase, 6 drivers (0°, 60°, 120°, 180°, 240°, 320°) 001 = 5-phase, 5 drivers (0°, 72°, 144°, 216°, 288°, OFF) 010 = 4-phase, 4 drivers (0°, 90°, 180°, 270°, OFF, OFF) 011 = 3-phase, 3 drivers (0°, 120°, 240°, OFF, OFF, OFF) 100 = 2-phase, 2 drivers (0°, 180°, OFF, OFF, OFF, OFF) 101 = 3-phase, 6 drivers (0°, 0°, 120°, 120°, 240°, 240°) 110 = 2-phase, 6 drivers (0°, 0°, 0°, 180°, 180°, 180°) 111 = 1-phase, 6 drivers (0°, 0°, 0°, 0°, 0°, 0°)
PWM_FREQ	3:0	R/W	0h = 4,808Hz (11-bit) 1h = 6,010Hz (10-bit) 2h = 7,212Hz (10-bit) 3h = 8,414Hz (10-bit) 4h = 9,616Hz (10-bit) 5h = 12,020Hz (9-bit) 6h = 13,222Hz (9-bit) 7h = 14,424Hz (9-bit) 8h = 15,626Hz (9-bit) 9h = 16,828Hz (9-bit) Ah = 18,030Hz (9-bit) Bh = 19,232Hz (9-bit) Ch = 24,040Hz (8-bit) Dh = 28,848Hz (8-bit) Eh = 33,656Hz (8-bit) Fh = 38,464Hz(8-bit)

CFG6

Address A6h

CFG6 register

7	6	5	4	3	2	1	0
BOOST_FREQ[1:0]		VBOOST[5:0]					

Name	Bit	Access	Description
BOOST_FREQ	7:6	R/W	Set boost switching frequency when BOOST_FSET_EN = 0. 00 = 312 kHz 01 = 625 kHz 10 = 1250 kHz 11 = undefined
VBOOST	5:0	R/W	Boost output voltage. When ADAPTIVE = 1, this is the boost minimum and initial voltage.

CFG7

Address A7h

CFG7 register							
7	6	5	4	3	2	1	0
RESERVED		EN_DRV3	EN_DRV2	RESERVED		IBOOST_LIM[1:0]	

Name	Bit	Access	Description
RESERVED	7:6		
EN_DRV3	5	R/W	Selects boost driver strength to set boost slew rate. See EMI Reduction section for more detail. 0 = Driver3 disabled 1 = Driver3 enabled
EN_DRV2	4	R/W	Selects boost driver strength to set boost slew rate. See EMI Reduction section for more detail. 0 = Driver2 disabled 1 = Driver2 enabled
RESERVED	3:2	R/W	
IBOOST_LIM	1:0	R/W	Select boost inductor current limit (IBOOST_LIM_2X = 0 / IBOOST_LIM_2X = 1) 00 = 0.9A / 1.6A 01 = 1.2A / 2.1A 10 = 1.5A / 2.6A 11 = 1.8A / not permitted

CFG9

Address A9h

CFG9 register							
7	6	5	4	3	2	1	0
VBOOST_MAX[2:0]			JUMP_EN	JUMP_THRESHOLD[1:0]		JUMP_VOLTAGE[1:0]	

Name	Bit	Access	Description
VBOOST_MAX	7:5	R/W	Select the maximum boost voltage (typ values) (VBOOST_RANGE = 0 / VBOOST_RANGE = 1) 010 = NA / 21V 011 = NA / 25V 100 = 21V / 30V 101 = 25V / 34.5V 110 = 30V / 39V 111 = 34V / 43V
JUMP_EN	4	R/W	Enable JUMP detection on the PWM input.
JUMP_THRESHOLD	3:2	R/W	Select JUMP threshold: 00 = 10% 01 = 30% 10 = 50% 11 = 70%
JUMP_VOLTAGE	1:0	R/W	Select JUMP voltage: 00 = 0.5V 01 = 1V 10 = 2V 11 = 4V

CFGA

Address AAh

CFGA register							
7	6	5	4	3	2	1	0
SSCLK_EN	RESERVED	RESERVED		ADAPTIVE	DRIVER_HEADROOM[2:0]		

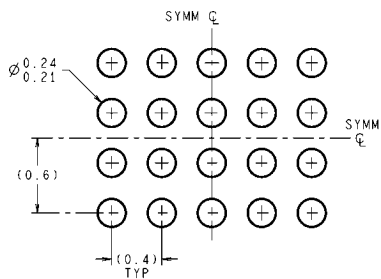| Name	Bit	Access	Description
SSCLK_EN	7	R/W	Enable spread spectrum function.
RESERVED	6	R/W	
RESERVED	5:4	R/W	
ADAPTIVE	3	R/W	Enable adaptive boost control.
DRIVER_HEADROOM	2:0	R/W	LED driver headroom control. This sets the LOW comparator threshold and contributes to the MID comparator threshold. 000 = HEADROOM_OFFSET + 875 mV 001 = HEADROOM_OFFSET + 750 mV 010 = HEADROOM_OFFSET + 625 mV 011 = HEADROOM_OFFSET + 500 mV 100 = HEADROOM_OFFSET + 375 mV 101 = HEADROOM_OFFSET + 250 mV 110 = HEADROOM_OFFSET + 125 mV 111 = HEADROOM_OFFSET mV

CFGE

Address AEh

CFGE register

7	6	5	4	3	2	1	0
STEP_UP[1:0]		STEP_DN[1:0]		LED_FAULT_TH[2:0]		LED_COMP_HYST[1:0]	

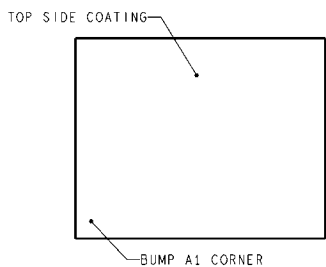| Name	Bit	Access	Description
STEP_UP	7:6	R/W	Adaptive headroom UP step size 00 = 105 mV 01 = 210 mV 10 = 420 mV 11 = 840 mV
STEP_DN	5:4	R/W	Adaptive headroom DOWN step size 00 = 105 mV 01 = 210 mV 10 = 420 mV 11 = 840 mV
LED_FAULT_TH	3:2	R/W	LED headroom fault threshold. This sets the HIGH comparator threshold. 00 = 5V 01 = 4V 10 = 3V 11 = 2V
LED_COMP_HYST	1:0	R/W	LED headrom comparison hysteresis. This sets the MID comparator threshold. 00 = DRIVER_HEADROOM + 1000 mV 01 = DRIVER_HEADROOM + 750 mV 10 = DRIVER_HEADROOM + 500 mV 11 = DRIVER_HEADROOM + 250 mV

CFGF

Address AFh

CFGF register

7	6	5	4	3	2	1	0
REVISION							

Name	Bit	Access	Description
REV	7:0	R/W	EPROM Settings Revision ID code

Physical Dimensions inches (millimeters) unless otherwise noted

Ø 0.24
0.21

SYMM ℄

SYMM ℄

(0.6)

(0.4) TYP

LAND PATTERN RECOMMENDATION

TOP SIDE COATING

BUMP A1 CORNER

DIMENSIONS ARE IN MILLIMETERS
DIMENSIONS IN ( ) FOR REFERENCE ONLY

C

X3

0.125
0.050

BUMP

SILICON

0.205
0.165

20X Ø 0.28
0.25

⊕ | 0.005 Ⓢ | C | A Ⓢ | B Ⓢ |

B

X2

SYMM ℄

4
3
2
1

0.4 TYP

SYMM ℄ X1

E D C B A

0.4 TYP

A
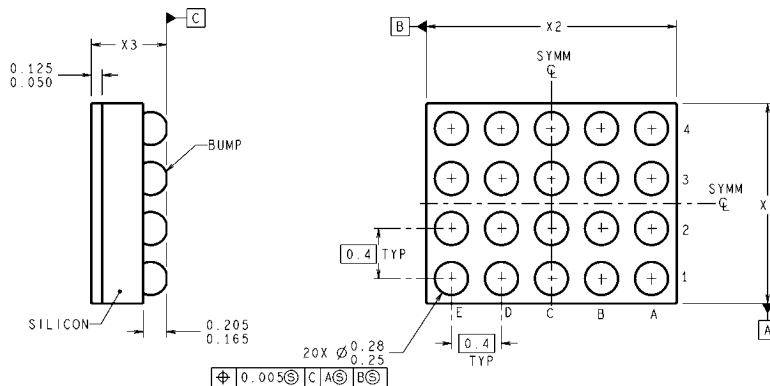
TMD20XXX (Rev D)

X1 = 1.715 ±0.03 mm
X2 = 2.376 ±0.03 mm
X3 = 0.600 ±0.075 mm

NS Package Number TMD20EQA
(See AN-1112 for PCB Design and Assembly Recommendations)

DIMENSIONS ARE IN MILLIMETERS
DIMENSIONS IN ( ) FOR REFERENCE ONLY

RECOMMENDED LAND PATTERN

PIN 1 INDEX AREA
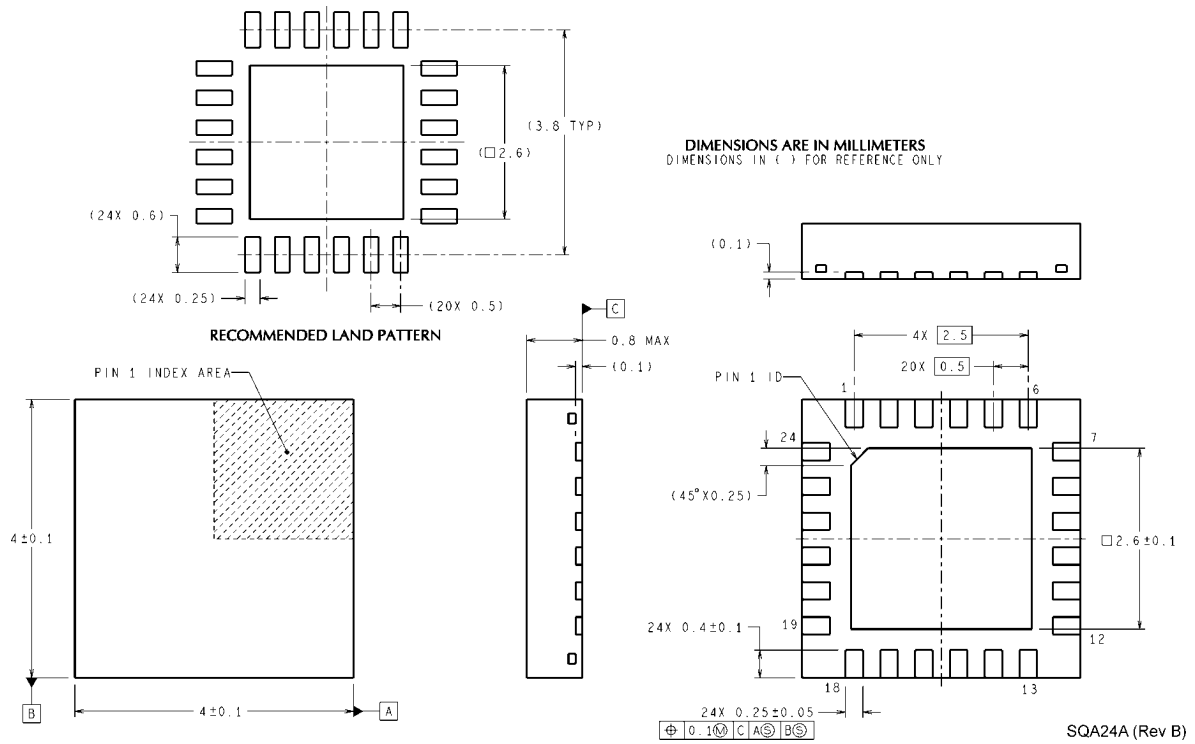
SQA24A (Rev B)

NS Package Number SQA24A
(See AN-1187 for PCB Design and Assembly Recommendations)

Notes

Notes

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